

# DLP4621-Q1 0.46 インチ 0.9 メガピクセル・デジタル・マイクロミラー・デバイス、車外照明向け

## 1 特長

- 車載アプリケーション認定済み
  - DMD アレイの動作温度範囲: -40°C ~ 105°C
- DLP4621-Q1 車載用チップセットには以下のものが含まれます。
  - DLP4621-Q1 DMD
  - DLPC231-Q1 DMD コントローラ
  - TPS99001-Q1 システム管理および照明コントローラ
- 0.46 インチの対角のマイクロミラー アレイ
  - 7.6μm のマイクロミラーピッチ
  - ±12° のマイクロミラー傾斜角
  - 下位 照明による高効率と小型エンジン サイズの実現
  - 0.9 メガピクセル アレイ (960 × 960、2:1) による高解像度でアスペクト比の大きい車載アプリケーションの実現
  - LED またはレーザー照明に対応可能
- 600MHz SubLVDS DMD インターフェイスによる低い消費電力と放射妨害
- 上限や下限の温度でも 10kHz の DMD リフレッシュレートを維持
- DMD メモリセルの内蔵セルフ テスト (BIST)

## 2 アプリケーション

- 高解像度ヘッドライト
- LIDAR 光フィルタ
- シンボル投影
- パーソナル化

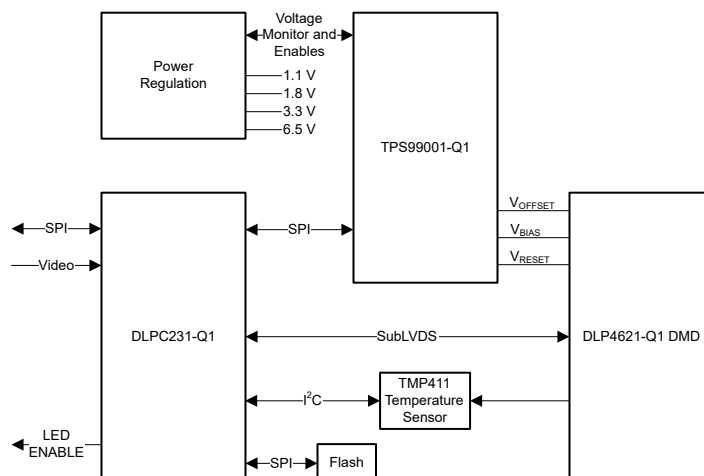
## 3 概要

DLP® DLP4621-Q1 車載用デジタル マイクロミラー デバイス (DMD) は、DLPC231-Q1 DMD コントローラや TPS99001-Q1 システム管理および照明コントローラとの組み合わせにより、高性能の高解像度ヘッドライト システムを実現します。2:1 のアスペクト比によって非常に大きいアスペクト比の設計に対応可能であり、また、0.9 メガピクセルの解像度により高解像度シンボル投影と適応型駆動ビーム アプリケーションを実現します。業界最高レベルの LED およびレーザー 技術を採用することで、DLP4621-Q1 の光学スルーputは、光束強度が最大になるように最適化されています。DLP4621-Q1 車載用 DMD マイクロミラー アレイは、高効率でより小型の光学エンジン設計が可能な底面照明用に構成されています。システム コストを最適化するため、DLP4621-Q1 デバイスはパネル パッケージで供給されます。このパッケージは、DMD アレイへの熱抵抗が小さいため、効率的なサーマルソリューションを実現できます。

### 製品情報

| 部品番号       | パッケージ (1) (2) | パッケージ サイズ       |
|------------|---------------|-----------------|
| DLP4621-Q1 | FQX           | 25.2mm × 11.0mm |

- 詳細については、[Mechanical, Packaging, and Orderable Information](#) を参照してください。
- このデータシートは、ヘッドライト アプリケーションでの本 DMD の仕様とアプリケーションに対応しています。ヘッドアップ ディスプレイの仕様とアプリケーション情報については、[DLP4620S-Q1 DLP® デジタル ミラー デバイス \(DMD\) データシート](#)を参照してください。



DLP4621-Q1DLP チップセットのシステム ブロック図



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## 4 Pin Configuration and Functions

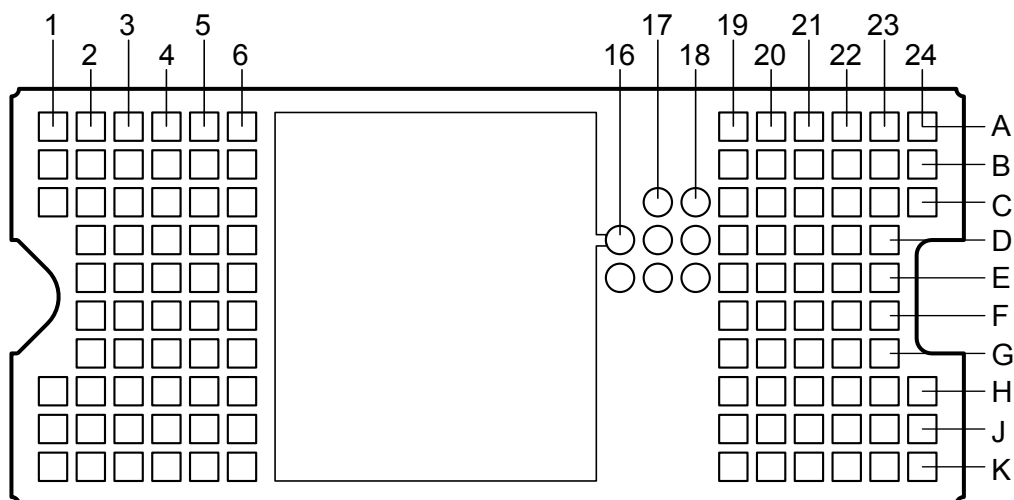


図 4-1. FQX Package 120-Pin LGA Bottom View

表 4-1. Pin Functions—Connector Pins

| PIN         |     | TYPE | SIGNAL  | DATA RATE | DESCRIPTION    |
|-------------|-----|------|---------|-----------|----------------|
| NAME        | NO. |      |         |           |                |
| DATA INPUTS |     |      |         |           |                |
| D_AN(0)     | A3  | I    | SubLVDS | Double    | Data, Negative |
| D_AN(1)     | B1  | I    | SubLVDS | Double    | Data, Negative |
| D_AN(2)     | C2  | I    | SubLVDS | Double    | Data, Negative |
| D_AN(3)     | F2  | I    | SubLVDS | Double    | Data, Negative |
| D_AN(4)     | H2  | I    | SubLVDS | Double    | Data, Negative |
| D_AN(5)     | K1  | I    | SubLVDS | Double    | Data, Negative |
| D_AN(6)     | K4  | I    | SubLVDS | Double    | Data, Negative |
| D_AN(7)     | K6  | I    | SubLVDS | Double    | Data, Negative |
| D_AP(0)     | A2  | I    | SubLVDS | Double    | Data, Positive |
| D_AP(1)     | C1  | I    | SubLVDS | Double    | Data, Positive |
| D_AP(2)     | D2  | I    | SubLVDS | Double    | Data, Positive |
| D_AP(3)     | E2  | I    | SubLVDS | Double    | Data, Positive |
| D_AP(4)     | G2  | I    | SubLVDS | Double    | Data, Positive |
| D_AP(5)     | K2  | I    | SubLVDS | Double    | Data, Positive |
| D_AP(6)     | K3  | I    | SubLVDS | Double    | Data, Positive |
| D_AP(7)     | K5  | I    | SubLVDS | Double    | Data, Positive |
| D_BN(0)     | A22 | I    | SubLVDS | Double    | Data, Negative |
| D_BN(1)     | B24 | I    | SubLVDS | Double    | Data, Negative |
| D_BN(2)     | D23 | I    | SubLVDS | Double    | Data, Negative |
| D_BN(3)     | F23 | I    | SubLVDS | Double    | Data, Negative |

表 4-1. Pin Functions—Connector Pins (続き)

| PIN                            |     | TYPE | SIGNAL  | DATA RATE | DESCRIPTION                                                                              |
|--------------------------------|-----|------|---------|-----------|------------------------------------------------------------------------------------------|
| NAME                           | NO. |      |         |           |                                                                                          |
| D_BN(4)                        | H23 | I    | SubLVDS | Double    | Data, Negative                                                                           |
| D_BN(5)                        | K24 | I    | SubLVDS | Double    | Data, Negative                                                                           |
| D_BN(6)                        | K21 | I    | SubLVDS | Double    | Data, Negative                                                                           |
| D_BN(7)                        | K19 | I    | SubLVDS | Double    | Data, Negative                                                                           |
| D_BP(0)                        | A23 | I    | SubLVDS | Double    | Data, Positive                                                                           |
| D_BP(1)                        | C24 | I    | SubLVDS | Double    | Data, Positive                                                                           |
| D_BP(2)                        | C23 | I    | SubLVDS | Double    | Data, Positive                                                                           |
| D_BP(3)                        | E23 | I    | SubLVDS | Double    | Data, Positive                                                                           |
| D_BP(4)                        | G23 | I    | SubLVDS | Double    | Data, Positive                                                                           |
| D_BP(5)                        | K23 | I    | SubLVDS | Double    | Data, Positive                                                                           |
| D_BP(6)                        | K22 | I    | SubLVDS | Double    | Data, Positive                                                                           |
| D_BP(7)                        | K20 | I    | SubLVDS | Double    | Data, Positive                                                                           |
| DCLK_AN                        | J1  | I    | SubLVDS | Double    | Clock, Negative                                                                          |
| DCLK_AP                        | H1  | I    | SubLVDS | Double    | Clock, Positive                                                                          |
| DCLK_BN                        | J24 | I    | SubLVDS | Double    | Clock, Negative                                                                          |
| DCLK_BP                        | H24 | I    | SubLVDS | Double    | Clock, Positive                                                                          |
| LS_CLKN                        | C3  | I    | SubLVDS | Single    | Clock for Low Speed Interface, Negative                                                  |
| LS_CLKP                        | C4  | I    | SubLVDS | Single    | Clock for Low Speed Interface, Positive                                                  |
| LS_WDATAN                      | C5  | I    | SubLVDS | Single    | Write Data for Low Speed Interface, Negative                                             |
| LS_WDATAP                      | C6  | I    | SubLVDS | Single    | Write Data for Low Speed Interface, Positive                                             |
| <b>CONTROL INPUTS</b>          |     |      |         |           |                                                                                          |
| DMD_DEN_ARSTZ                  | E6  | I    | LPSDR   |           | Asynchronous Reset Active Low. Logic High Enables DMD                                    |
| LS_RDATA_A                     | E19 | O    | LPSDR   | Single    | Read Data for Low Speed Interface                                                        |
| LS_RDATA_B                     | F19 | O    | LPSDR   | Single    | Read Data for Low Speed Interface                                                        |
| <b>TEMPERATURE SENSE DIODE</b> |     |      |         |           |                                                                                          |
| TEMP_N                         | F6  | O    |         |           | Calibrated temperature diode used to assist accurate temperature measurements of DMD die |
| TEMP_P                         | G6  | I    |         |           |                                                                                          |

**表 4-1. Pin Functions—Connector Pins (続き)**

| PIN     |     | TYPE  | SIGNAL | DATA RATE | DESCRIPTION                                                                                                                  |
|---------|-----|-------|--------|-----------|------------------------------------------------------------------------------------------------------------------------------|
| NAME    | NO. |       |        |           |                                                                                                                              |
| POWER   |     |       |        |           |                                                                                                                              |
| VBIAS   | A4  | Power |        |           | Supply voltage for positive bias level at micromirrors                                                                       |
| VBIAS   | A21 | Power |        |           |                                                                                                                              |
| VOFFSET | B3  | Power |        |           | Supply voltage for high-voltage CMOS core logic.<br>Supply voltage for offset level at micromirrors                          |
| VOFFSET | B4  | Power |        |           |                                                                                                                              |
| VOFFSET | B21 | Power |        |           |                                                                                                                              |
| VOFFSET | B22 | Power |        |           |                                                                                                                              |
| VOFFSET | J4  | Power |        |           |                                                                                                                              |
| VOFFSET | J21 | Power |        |           |                                                                                                                              |
| VRESET  | B6  | Power |        |           | Supply voltage for negative reset level at micromirrors                                                                      |
| VRESET  | B19 | Power |        |           |                                                                                                                              |
| VDD     | A5  | Power |        |           | Supply voltage for Low Voltage CMOS core logic;<br>for LPSDR inputs; for normal high level at micromirror address electrodes |
| VDD     | A20 | Power |        |           |                                                                                                                              |
| VDD     | C20 | Power |        |           |                                                                                                                              |
| VDD     | D4  | Power |        |           |                                                                                                                              |
| VDD     | D19 | Power |        |           |                                                                                                                              |
| VDD     | D21 | Power |        |           |                                                                                                                              |
| VDD     | E3  | Power |        |           |                                                                                                                              |
| VDD     | E22 | Power |        |           |                                                                                                                              |
| VDD     | F4  | Power |        |           |                                                                                                                              |
| VDD     | G3  | Power |        |           |                                                                                                                              |
| VDD     | G21 | Power |        |           |                                                                                                                              |
| VDD     | H22 | Power |        |           |                                                                                                                              |
| VDD     | J3  | Power |        |           |                                                                                                                              |
| VDD     | J6  | Power |        |           |                                                                                                                              |
| VDD     | J19 | Power |        |           |                                                                                                                              |
| VDDI    | E5  | Power |        |           | Supply voltage for SubLVDS receivers                                                                                         |
| VDDI    | E20 | Power |        |           |                                                                                                                              |
| VDDI    | F5  | Power |        |           |                                                                                                                              |
| VDDI    | F20 | Power |        |           |                                                                                                                              |
| VDDI    | G5  | Power |        |           |                                                                                                                              |
| VDDI    | G20 | Power |        |           |                                                                                                                              |
| VDDI    | H5  | Power |        |           |                                                                                                                              |
| VDDI    | H20 | Power |        |           |                                                                                                                              |

表 4-1. Pin Functions—Connector Pins (続き)

| PIN  |     | TYPE   | SIGNAL | DATA RATE | DESCRIPTION                         |
|------|-----|--------|--------|-----------|-------------------------------------|
| NAME | NO. |        |        |           |                                     |
| VSS  | A1  | Ground |        |           | Common return. Ground for all power |
| VSS  | A6  | Ground |        |           |                                     |
| VSS  | A19 | Ground |        |           |                                     |
| VSS  | A24 | Ground |        |           |                                     |
| VSS  | B2  | Ground |        |           |                                     |
| VSS  | B5  | Ground |        |           |                                     |
| VSS  | B20 | Ground |        |           |                                     |
| VSS  | B23 | Ground |        |           |                                     |
| VSS  | C19 | Ground |        |           |                                     |
| VSS  | C21 | Ground |        |           |                                     |
| VSS  | C22 | Ground |        |           |                                     |
| VSS  | D3  | Ground |        |           |                                     |
| VSS  | D5  | Ground |        |           |                                     |
| VSS  | D6  | Ground |        |           |                                     |
| VSS  | D20 | Ground |        |           |                                     |
| VSS  | D22 | Ground |        |           |                                     |
| VSS  | E4  | Ground |        |           |                                     |
| VSS  | E21 | Ground |        |           |                                     |
| VSS  | F3  | Ground |        |           |                                     |
| VSS  | F21 | Ground |        |           |                                     |
| VSS  | F22 | Ground |        |           |                                     |
| VSS  | G4  | Ground |        |           |                                     |
| VSS  | G19 | Ground |        |           |                                     |
| VSS  | G22 | Ground |        |           |                                     |
| VSS  | H3  | Ground |        |           |                                     |
| VSS  | H4  | Ground |        |           |                                     |
| VSS  | H6  | Ground |        |           |                                     |
| VSS  | H19 | Ground |        |           |                                     |
| VSS  | H21 | Ground |        |           |                                     |
| VSS  | J2  | Ground |        |           |                                     |
| VSS  | J5  | Ground |        |           |                                     |
| VSS  | J20 | Ground |        |           |                                     |
| VSS  | J22 | Ground |        |           |                                     |
| VSS  | J23 | Ground |        |           |                                     |

**表 4-2. Pin Functions—Test Pads**

| Pin Number | SYSTEM BOARD                                |
|------------|---------------------------------------------|
| C17        | Do not connect.                             |
| C18        | Do not connect.                             |
| D16        | Do not connect. Internally connected to VSS |
| D17        | Do not connect.                             |
| D18        | Do not connect.                             |
| E16        | Do not connect.                             |
| E17        | Do not connect.                             |
| E18        | Do not connect.                             |

## 5 Specifications

### 5.1 Absolute Maximum Ratings

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device is not implied at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure above or below the Recommended Operating Conditions for extended periods may affect device reliability.

|                                                           |                                                                                                     | MIN  | MAX             | UNIT |
|-----------------------------------------------------------|-----------------------------------------------------------------------------------------------------|------|-----------------|------|
| <b>SUPPLY VOLTAGE</b>                                     |                                                                                                     |      |                 |      |
| $V_{DD}$                                                  | Supply voltage for LVCMOS core logic <sup>(1)</sup><br>Supply voltage for LPSDR low speed interface | –0.5 | 2.3             | V    |
| $V_{DDI}$                                                 | Supply voltage for SubLVDS receivers <sup>(1)</sup>                                                 | –0.5 | 2.3             | V    |
| $V_{OFFSET}$                                              | Supply voltage for HVCMOS and micromirror electrode <sup>(1) (2)</sup>                              | –0.5 | 8.75            | V    |
| $V_{BIAS}$                                                | Supply voltage for micromirror electrode <sup>(1)</sup>                                             | –0.5 | 17              | V    |
| $V_{RESET}$                                               | Supply voltage for micromirror electrode <sup>(1)</sup>                                             | –11  | 0.5             | V    |
| $ V_{DDI} - V_{DD} $                                      | Supply voltage delta (absolute value) <sup>(3)</sup>                                                |      | 0.3             | V    |
| $ V_{BIAS} - V_{OFFSET} $                                 | Supply voltage delta (absolute value) <sup>(4)</sup>                                                |      | 8.75            | V    |
| $ V_{BIAS} - V_{RESET} $                                  | Supply voltage delta (absolute value) <sup>(5)</sup>                                                |      | 28              | V    |
| <b>INPUT VOLTAGE</b>                                      |                                                                                                     |      |                 |      |
| Input voltage for LVCMOS Inputs <sup>(1)</sup>            |                                                                                                     | –0.5 | $V_{DD} + 0.5$  | V    |
| Input voltage for other inputs SubLVDS <sup>(1) (6)</sup> |                                                                                                     | –0.5 | $V_{DDI} + 0.5$ | V    |
| <b>INPUT PINS</b>                                         |                                                                                                     |      |                 |      |
| $ V_{ID} $                                                | SubLVDS input differential voltage (absolute value) <sup>(6)</sup>                                  |      | 810             | mV   |
| $ I_{ID} $                                                | SubLVDS input differential current                                                                  |      | 10              | mA   |
| <b>CLOCK FREQUENCY</b>                                    |                                                                                                     |      |                 |      |
| $F_{max\_LS}$                                             | Clock frequency for low speed interface LS_CLK                                                      | 100  | 130             | MHz  |
| <b>TEMPERATURE DIODE</b>                                  |                                                                                                     |      |                 |      |
| $I_{TEMP\_DIODE}$                                         | Max current source into temperature diode                                                           |      | 120             | μA   |
| <b>ENVIRONMENTAL</b>                                      |                                                                                                     |      |                 |      |
| $T_{ARRAY}$                                               | Operating DMD array temperature                                                                     | –40  | 105             | °C   |

- (1) All voltage values are with respect to the ground terminals ( $V_{SS}$ ). The following power supplies are all required to operate the DMD:  $V_{DD}$ ,  $V_{DDI}$ ,  $V_{OFFSET}$ ,  $V_{BIAS}$ , and  $V_{RESET}$ . All  $V_{SS}$  connections are also required.
- (2)  $V_{OFFSET}$  supply transients must fall within specified voltages.
- (3) Exceeding the recommended allowable absolute voltage difference between  $V_{DDI}$  and  $V_{DD}$  may result in excessive current draw and permanent damage to the device.
- (4) Exceeding the recommended allowable absolute voltage difference between  $V_{BIAS}$  and  $V_{OFFSET}$  may result in excessive current draw and permanent damage to the device.
- (5) Exceeding the recommended allowable absolute voltage difference between  $V_{BIAS}$  and  $V_{RESET}$  may result in excessive current draw and permanent damage to the device.
- (6) This maximum input voltage rating applies when each input of a differential pair is at the same voltage potential. Sub-LVDS differential inputs must not exceed the specified limit or damage to the internal termination resistors may result.

### 5.2 Storage Conditions

Applicable for the DMD as a component or non-operating in a system.

|           |                         | MIN | MAX | UNIT |
|-----------|-------------------------|-----|-----|------|
| $T_{stg}$ | DMD storage temperature | –40 | 125 | °C   |

## 5.3 ESD Ratings

|             |                         |                                                         | Value | UNIT |
|-------------|-------------------------|---------------------------------------------------------|-------|------|
| $V_{(ESD)}$ | Electrostatic discharge | Human body model (HBM), per AEC Q100-002 <sup>(1)</sup> | ±1000 | V    |
|             |                         | Charged device model (CDM), per AEC Q100-011            | ±750  |      |

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

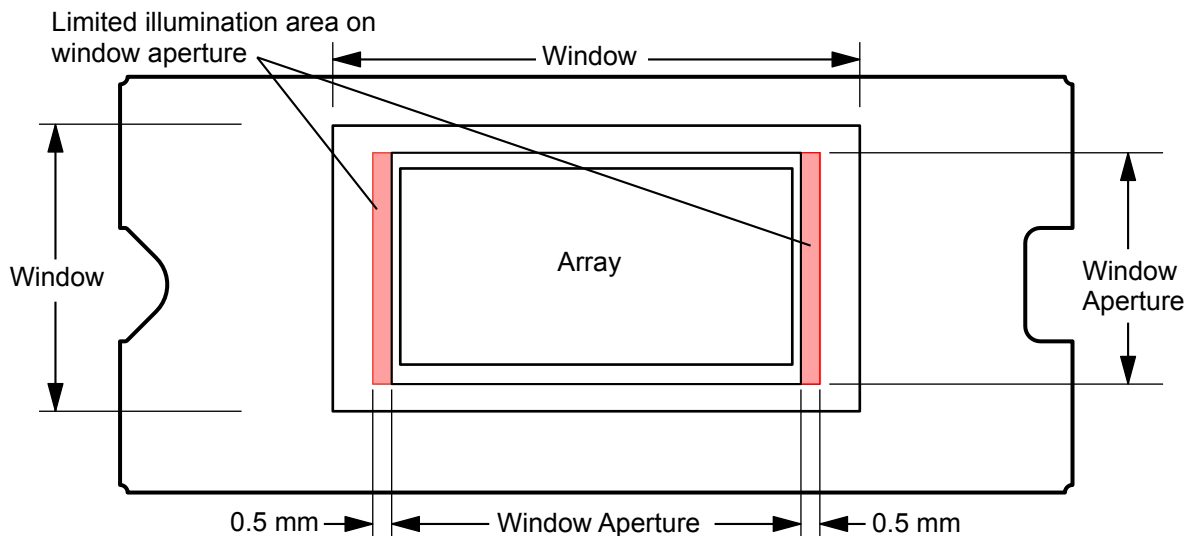
## 5.4 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup> <sup>(2)</sup>

|                                  |                                                                                                            | MIN  | NOM | MAX   | UNIT               |
|----------------------------------|------------------------------------------------------------------------------------------------------------|------|-----|-------|--------------------|
| <b>SUPPLY VOLTAGE</b>            |                                                                                                            |      |     |       |                    |
| $V_{DD}$                         | Supply voltage for LVCMOS core logic<br>Supply voltage for LPDSR low-speed interface                       | 1.65 | 1.8 | 1.95  | V                  |
| $V_{DDI}$                        | Supply voltage for SubLVDS receivers                                                                       | 1.65 | 1.8 | 1.95  | V                  |
| $V_{OFFSET}$                     | Supply voltage for HVCMOS and micromirror electrode <sup>(3)</sup>                                         | 8.25 | 8.5 | 8.75  | V                  |
| $V_{BIAS}$                       | Supply voltage for mirror electrode                                                                        | 15.5 | 16  | 16.5  | V                  |
| $V_{RESET}$                      | Supply voltage for micromirror electrode                                                                   | −9.5 | −10 | −10.5 | V                  |
| $ V_{DDI} - V_{DD} $             | Supply voltage delta (absolute value) <sup>(4)</sup>                                                       |      |     | 0.3   | V                  |
| $ V_{BIAS} - V_{OFFSET} $        | Supply voltage delta (absolute value) <sup>(5)</sup>                                                       |      |     | 8.75  | V                  |
| $ V_{BIAS} - V_{RESET} $         | Supply voltage delta (absolute value) <sup>(6)</sup>                                                       |      |     | 28    | V                  |
| <b>LOW-SPEED LPDSR INTERFACE</b> |                                                                                                            |      |     |       |                    |
| $f_{clock\_LS}$                  | Clock frequency for low speed interface LS_CLK                                                             | 108  |     | 120   | MHz                |
| $DCD_{IN}$                       | LSIF duty cycle distortion (LS_CLK)                                                                        | 44   |     | 56    | %                  |
| <b>SUBLVDS INTERFACE</b>         |                                                                                                            |      |     |       |                    |
| $f_{clock\_HS}$                  | Clock frequency for high-speed interface DCLK                                                              |      |     | 600   | MHz                |
| $DCD_{IN}$                       | LVDS duty cycle distortion (DCLK)                                                                          | 44   |     | 56    | %                  |
| $ V_{ID} $                       | LVDS differential input voltage magnitude <sup>(7)</sup>                                                   | 150  | 250 | 350   | mV                 |
| $V_{CM}$                         | Common mode voltage <sup>(7)</sup>                                                                         | 700  | 900 | 1100  | mV                 |
| $V_{SUBLVDS}$                    | SubLVDS voltage <sup>(7)</sup>                                                                             | 525  |     | 1275  | mV                 |
| $Z_{LINE}$                       | Line differential impedance (PWB/trace)                                                                    | 90   | 100 | 110   | Ω                  |
| $Z_{IN}$                         | Internal differential termination resistance <sup>(8)</sup>                                                | 80   | 100 | 120   | Ω                  |
|                                  | 100-Ω differential PCD trace                                                                               | 6.35 |     | 152.4 | mm                 |
| <b>ENVIRONMENTAL</b>             |                                                                                                            |      |     |       |                    |
| $T_{ARRAY}$                      | Array Temperature <sup>(9)</sup> <sup>(11)</sup>                                                           | −40  |     | 105   | °C                 |
| <b>Illumination</b>              |                                                                                                            |      |     |       |                    |
| $ILL_{UV}$                       | Illumination, wavelength < 395 nm <sup>(10)</sup>                                                          |      |     | 2     | mW/cm <sup>2</sup> |
| $ILL_{OVERFILL}$                 | Illumination overfill maximum heat load in area shown in the <a href="#">Illumination Overfill Diagram</a> |      |     | 90    | mW/mm <sup>2</sup> |

- (1) Recommended Operating Conditions are applicable after the DMD is installed in the final product.
- (2) The following power supplies are all required to operate the DMD:  $V_{DD}$ ,  $V_{DDI}$ ,  $V_{OFFSET}$ ,  $V_{BIAS}$ , and  $V_{RESET}$ . All  $V_{SS}$  connections are also required.
- (3)  $V_{OFFSET}$  supply transients must fall within specified min/max voltages.
- (4) To prevent excess current, the supply voltage delta  $|V_{DDI} - V_{DD}|$  must be less than the specified limit.
- (5) To prevent excess current, the supply voltage delta  $|V_{BIAS} - V_{OFFSET}|$  must be less than the specified limit.
- (6) To prevent excess current, the supply voltage delta  $|V_{BIAS} - V_{RESET}|$  must be less than the specified limit.
- (7) See [Figure 5-6](#) and [Figure 5-7](#).
- (8) See [Figure 5-8](#).
- (9) DMD Active Array temperature can be calculated as shown in [Micromirror Array Temperature Calculation](#) section.
- (10) The maximum operation conditions for operating temperature and UV illumination shall not be implemented simultaneously.
- (11) Operating profile information for device micromirror landed duty-cycle and temperature may be provided if requested.

### 5.4.1 Illumination Overfill Diagram



5-1. Illumination Overfill Diagram

## 5.5 Thermal Information

| THERMAL METRIC     |                                                           | DLP4621-Q1 | UNIT |
|--------------------|-----------------------------------------------------------|------------|------|
|                    |                                                           | FQX        |      |
|                    |                                                           | 120 PINS   |      |
| Thermal resistance | Active area-to-test point 1 (TP1) <sup>(1) (2)</sup>      | 1.5        | °C/W |
| Thermal resistance | Active area-to-temperature sense diode <sup>(1) (2)</sup> | 0.5        | °C/W |

- (1) The DMD is designed to conduct absorbed and dissipated heat to the back of the package. The cooling system must be capable of maintaining the package within the temperature range specified in the *Recommended Operating Conditions* section. The total heat load on the DMD is largely driven by the incident light absorbed by the active area, although other contributions include light energy absorbed by the window aperture and electrical power dissipation of the array. Design optical systems to minimize the light energy falling outside the window's clear aperture since any additional thermal load in this area can significantly degrade the reliability of the device.
- (2) The thermal resistance values provided here assumes a non-uniform illumination profile. Refer to the [Micromirror Array Temperature Calculation](#) section for details.

## 5.6 Electrical Characteristics

Over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup>

| PARAMETER      |                                               | TEST CONDITIONS  | MIN | TYP | MAX | UNIT |
|----------------|-----------------------------------------------|------------------|-----|-----|-----|------|
| <b>CURRENT</b> |                                               |                  |     |     |     |      |
| $I_{DD}$       | Supply current: VDD <sup>(2)</sup>            | VDD = 1.95 V     |     |     | 220 | mA   |
| $I_{DDI}$      | Supply current: VDDI <sup>(2)</sup>           | VDDI = 1.95 V    |     |     | 62  | mA   |
| $I_{OFFSET}$   | Supply current: VOFFSET                       | VOFFSET = 8.75 V |     |     | 35  | mA   |
| $I_{BIAS}$     | Supply current: VBIAS                         | VBIAS = 16.5 V   |     |     | 1.5 | mA   |
| $I_{RESET}$    | Supply current: VRESET                        | VRESET = -10.5 V | -16 |     |     | mA   |
| <b>POWER</b>   |                                               |                  |     |     |     |      |
| $P_{DD}$       | Supply power dissipation: VDD <sup>(2)</sup>  | VDD = 1.95 V     |     |     | 430 | mW   |
| $P_{DDI}$      | Supply power dissipation: VDDI <sup>(2)</sup> | VDDI = 1.95 V    |     |     | 121 | mW   |
| $P_{OFFSET}$   | Supply power dissipation: VOFFSET             | VOFFSET = 8.75 V |     |     | 307 | mW   |
| $P_{BIAS}$     | Supply power dissipation: VBIAS               | VBIAS = 16.5 V   |     |     | 25  | mW   |
| $P_{RESET}$    | Supply power dissipation: VRESET              | VRESET = -10.5 V |     |     | 168 | mW   |

## 5.6 Electrical Characteristics (続き)

Over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup>

| PARAMETER             |                                         | TEST CONDITIONS                                   | MIN                   | TYP                   | MAX                   | UNIT |
|-----------------------|-----------------------------------------|---------------------------------------------------|-----------------------|-----------------------|-----------------------|------|
| P <sub>TOTAL</sub>    | Supply power dissipation: Total         |                                                   |                       |                       | 1045                  | mW   |
| <b>LVC MOS INPUT</b>  |                                         |                                                   |                       |                       |                       |      |
| V <sub>IH</sub>       | High-level input voltage <sup>(3)</sup> |                                                   | 0.7 × V <sub>DD</sub> |                       | V <sub>DD</sub> + 0.3 | V    |
| V <sub>IL</sub>       | Low-level input voltage <sup>(3)</sup>  |                                                   | -0.3                  | 0.3 × V <sub>DD</sub> |                       | V    |
| V <sub>IH(AC)</sub>   | AC input high voltage <sup>(3)</sup>    |                                                   | 0.8 × V <sub>DD</sub> |                       | V <sub>DD</sub> + 0.3 | V    |
| V <sub>IL(AC)</sub>   | AC input low voltage <sup>(3)</sup>     |                                                   | -0.3                  |                       | 0.2 × V <sub>DD</sub> | V    |
| V <sub>Hyst</sub>     | Input Hysteresis <sup>(3)</sup>         | See Figure 5-9                                    | 0.1 × V <sub>DD</sub> |                       | 0.4 × V <sub>DD</sub> | V    |
| I <sub>IL</sub>       | Low-level input current <sup>(3)</sup>  | V <sub>DD</sub> = 1.95 V; V <sub>I</sub> = 0 V    | -100                  |                       |                       | nA   |
| I <sub>IH</sub>       | High-level input current <sup>(3)</sup> | V <sub>DD</sub> = 1.95 V; V <sub>I</sub> = 1.95 V |                       |                       | 135                   | μA   |
| <b>LVC MOS OUTPUT</b> |                                         |                                                   |                       |                       |                       |      |
| V <sub>OH</sub>       | DC output high voltage <sup>(4)</sup>   | I <sub>OH</sub> = -2mA                            | 0.8 × V <sub>DD</sub> |                       |                       | V    |
| V <sub>OL</sub>       | DC output low voltage <sup>(4)</sup>    | I <sub>OL</sub> = 2mA                             |                       |                       | 0.2 × V <sub>DD</sub> | V    |
| I <sub>OZ</sub>       | High impedance output current           | V <sub>DD</sub> = 1.95V                           |                       |                       | 10                    | μA   |
| <b>CAPACITANCE</b>    |                                         |                                                   |                       |                       |                       |      |
| C <sub>IN</sub>       | Input capacitance LVC MOS               | F = 1 MHz                                         |                       |                       | 10                    | pF   |
|                       | Input capacitance SubLVDS               | F = 1 MHz                                         |                       |                       | 20                    | pF   |
| C <sub>OUT</sub>      | Output capacitance                      | F = 1 MHz                                         |                       |                       | 13                    | pF   |
| C <sub>TEMP</sub>     | Temperature sense diode capacitance     | F = 1 MHz                                         |                       |                       | 20                    | pF   |

(1) Device electrical characteristics are over *Recommended Operating Conditions* unless otherwise noted.

(2) Supply power dissipation based on non-compressed commands and data.

(3) LPSDR input specification are for pin DMD\_DEN\_ARSTZ.

(4) LPSDR output specification is for pins LS\_RDATA\_A and LS\_RDATA\_B.

## 5.7 Timing Requirements

Device electrical characteristics are over *Recommended Operating Conditions* unless otherwise noted

|                             |                                           |                                                        | MIN  | NOM  | MAX | UNIT |
|-----------------------------|-------------------------------------------|--------------------------------------------------------|------|------|-----|------|
| <b>Low-Speed Interface</b>  |                                           |                                                        |      |      |     |      |
| t <sub>r</sub>              | Rise slew rate <sup>(1) (2)</sup>         | (20% to 80%) × V <sub>DD</sub>                         | 0.25 |      |     | V/ns |
| t <sub>f</sub>              | Fall slew rate <sup>(1) (2)</sup>         | (80% to 20%) × V <sub>DD</sub>                         | 0.25 |      |     | V/ns |
| t <sub>c</sub>              | Cycle time LS_CLK                         |                                                        | 7.7  | 8.3  |     | ns   |
| t <sub>W(H)</sub>           | Pulse duration LS_CLK high <sup>(3)</sup> | 50% to 50% reference points                            | 3.1  |      |     | ns   |
| t <sub>W(L)</sub>           | Pulse duration LS_CLK low <sup>(3)</sup>  | 50% to 50% reference points                            | 3.1  |      |     | ns   |
| t <sub>su</sub>             | Setup time <sup>(3)</sup>                 | LS_WDATA valid before LS_CLK ↑ or LS_CLK ↓             | 1.5  |      |     | ns   |
| t <sub>h</sub>              | Hold time <sup>(3)</sup>                  | LS_WDATA valid after LS_CLK ↑ or LS_CLK ↓              | 1.5  |      |     | ns   |
| t <sub>WINDOW</sub>         | Window time                               | Setup time + hold time                                 | 3    |      |     | ns   |
| t <sub>DERATING</sub>       | Window time derating                      | For each 0.25 V/ns reduction in slew rate below 1 V/ns |      | 0.35 |     | ns   |
| <b>High-Speed Interface</b> |                                           |                                                        |      |      |     |      |
| t <sub>r</sub>              | Rise slew rate <sup>(2)</sup>             | 20% to 80% reference points                            | 0.7  | 1    |     | V/ns |
| t <sub>f</sub>              | Fall slew rate <sup>(2)</sup>             | 80% to 20% reference points                            | 0.7  | 1    |     | V/ns |
| t <sub>c</sub>              | Cycle time DCLK <sup>(3)</sup>            |                                                        | 1.61 | 1.67 |     | ns   |

## 5.7 Timing Requirements (続き)

Device electrical characteristics are over *Recommended Operating Conditions* unless otherwise noted

|                      |                                         |                             | MIN  | NOM | MAX  | UNIT |
|----------------------|-----------------------------------------|-----------------------------|------|-----|------|------|
| $t_{W(H)}$           | Pulse duration DCLK high <sup>(3)</sup> | 50% to 50% reference points | 0.75 |     |      | ns   |
| $t_{W(L)}$           | Pulse duration DCLK low <sup>(3)</sup>  | 50% to 50% reference points | 0.75 |     |      | ns   |
| $t_{WINDOW}$         | Window time <sup>(3)</sup> (4)          | Setup time + Hold time      | 0.3  |     |      | ns   |
| $t_{LVDS-EN+REFGEN}$ | Power-up receiver <sup>(5)</sup>        |                             |      |     | 2000 | ns   |

- (1) Specification is for DMD\_DEN\_ARSTZ pin. Refer to LPSDR input rise and fall slew rate in Figure 6-2.  
 (2) See Figure 5-3.  
 (3) See Figure 5-4.  
 (4) See Figure 5-5.  
 (5) Specification is for SubLVDS receiver time only and does not take into account commanding and latency after commanding.

### Electrical and Timing Diagrams

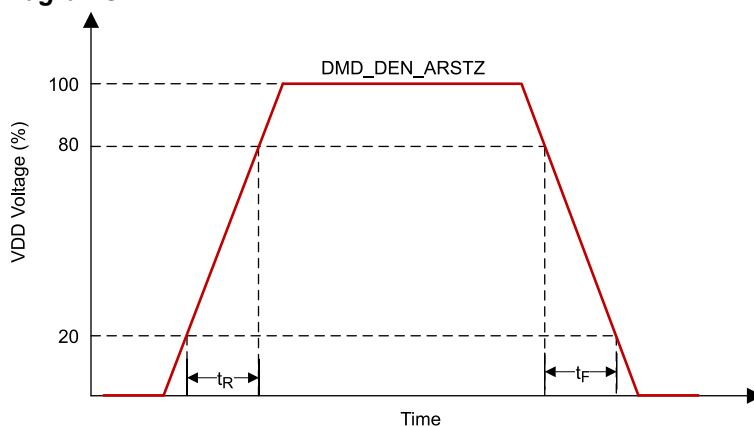


図 5-2. LPSDR Input Rise and Fall Slew Rate

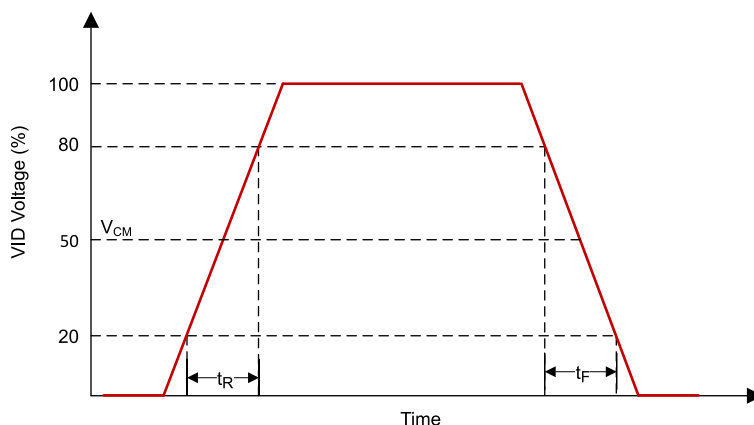
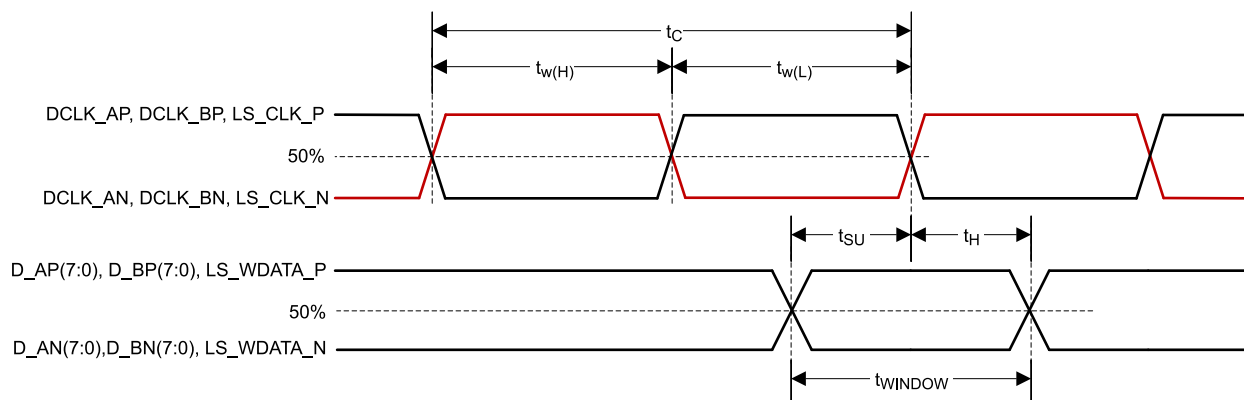
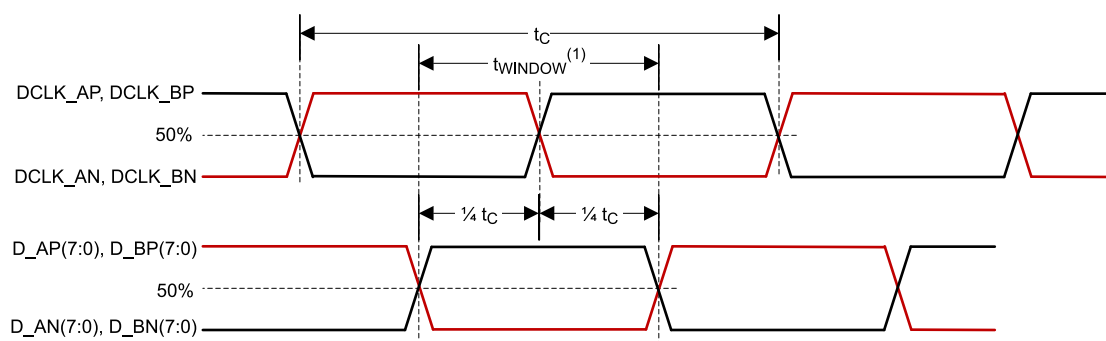


図 5-3. SubLVDS Input Rise and Fall Slew Rate

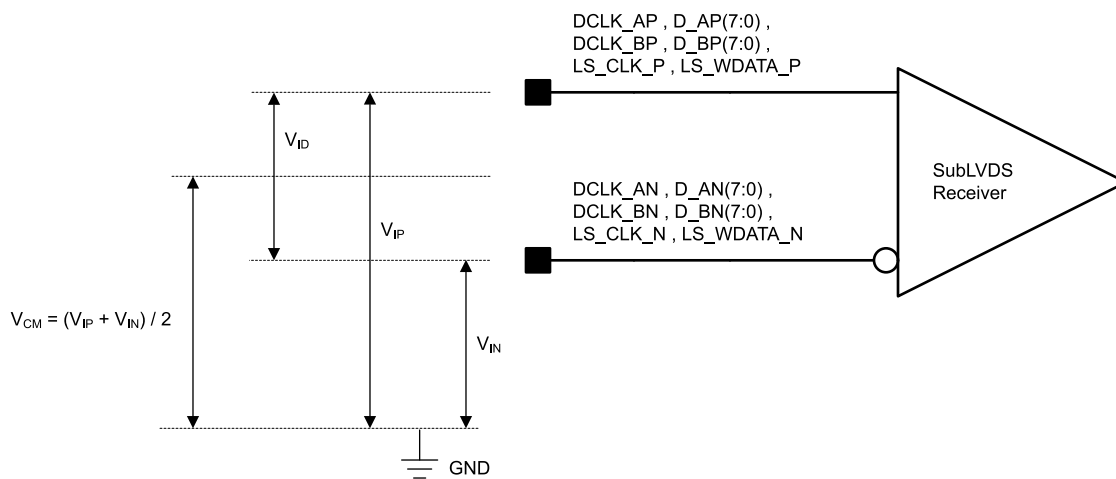


**図 5-4. SubLVDS Switching Parameters**



(1) High-speed training scan window

**図 5-5. High-Speed Training Scan Window**



**図 5-6. SubLVDS Voltage Parameters**

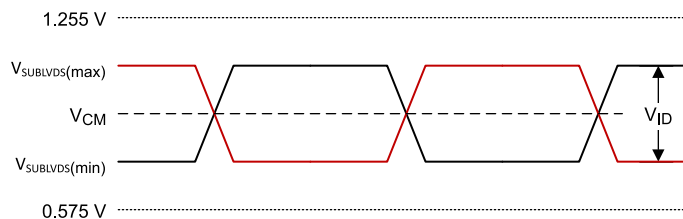


図 5-7. SubLVDS Waveform Parameters

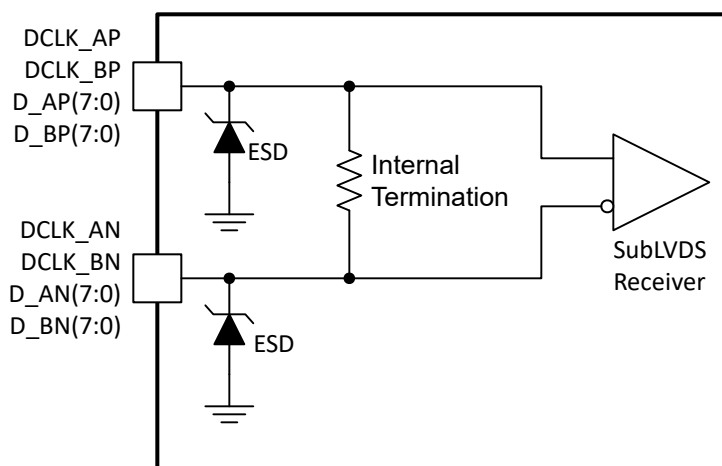


図 5-8. SubLVDS Equivalent Input Circuit

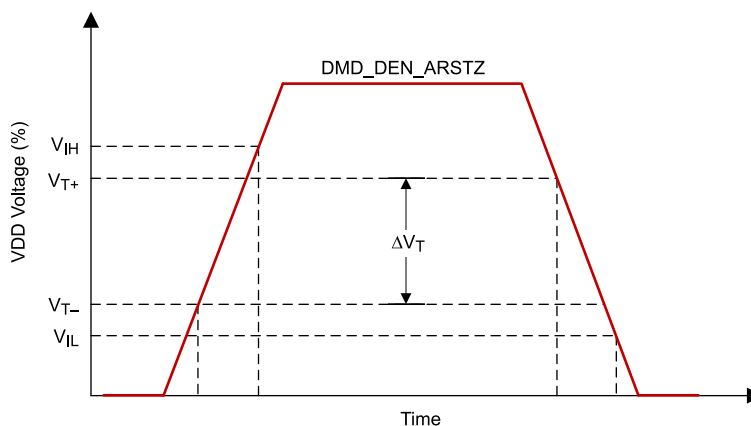


図 5-9. LPSDR Input Hysteresis

## 5.8 Switching Characteristics

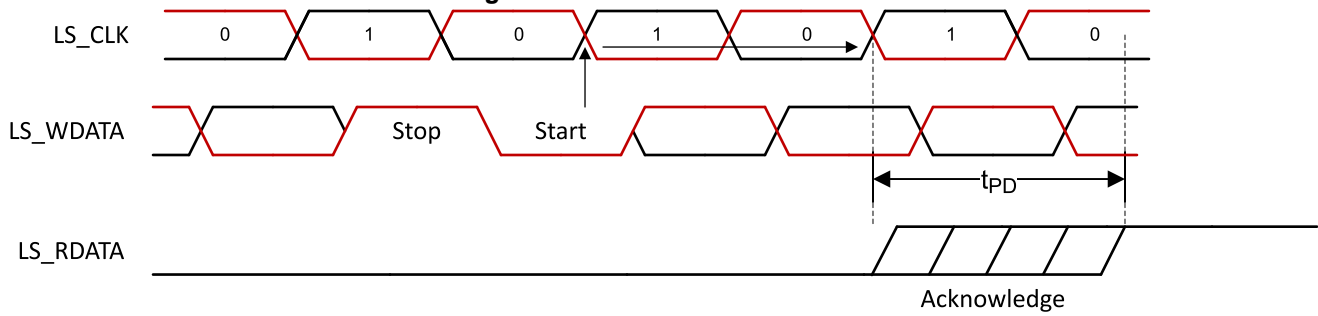
Over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

| PARAMETER | TEST CONDITIONS                                                                                                           | MIN | TYP | MAX | UNIT |
|-----------|---------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|------|
| $t_{PD}$  | Output propagation, clock to Q, rising edge of LS_CLK (differential clock signal) input to LS_RDATA output <sup>(2)</sup> |     |     | 15  | ns   |
|           | Slew rate, LS_RDATA                                                                                                       | 0.5 |     |     | V/ns |
|           | Output duty cycle distortion, LS_RDATA_A and LS_RDATA_B                                                                   | 40% |     | 60% |      |

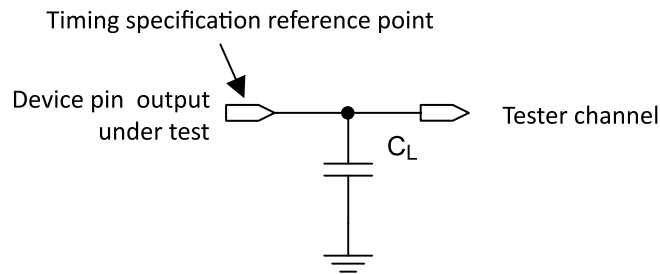
(1) Device electrical characteristics are over *Recommended Operating Conditions* unless otherwise noted.

(2) See 図 5-10 and 図 5-11.

### 5.8.1 LPSDR and Test Load Circuit Diagrams



5-10. LPSDR Read Out



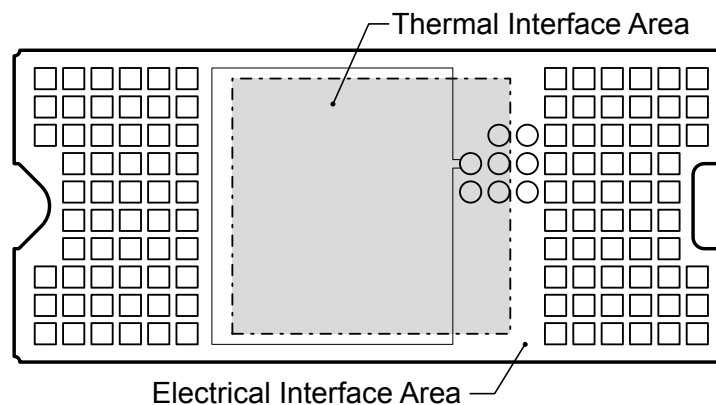
5-11. Test Load Circuit for Output Propagation Measurement

### 5.9 System Mounting Interface Loads

| PARAMETER                 | Condition                                                          | MIN | NOM | MAX | UNIT |
|---------------------------|--------------------------------------------------------------------|-----|-----|-----|------|
| Thermal interface area    | Maximum load uniformly distributed within each area <sup>(1)</sup> |     |     | 90  | N    |
| Electrical interface area | Maximum load uniformly distributed within each area <sup>(1)</sup> |     |     | 135 |      |

(1) See Figure 5-12.

### System Interface Loads Diagram



5-12. System Interface Loads

### 5.10 Micromirror Array Physical Characteristics

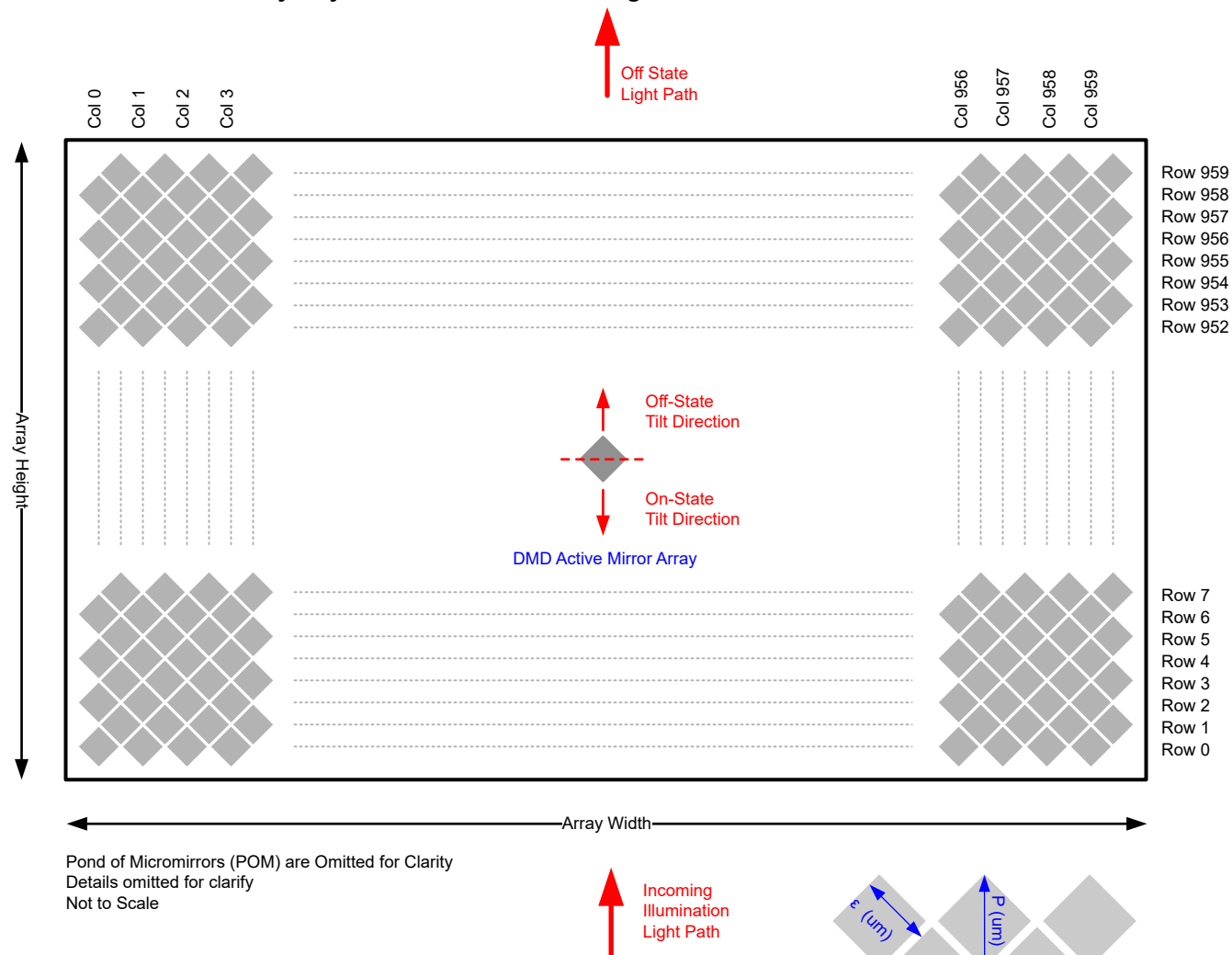
|            | PARAMETER                                                        | VALUE | UNIT          |
|------------|------------------------------------------------------------------|-------|---------------|
| M          | Number of active columns <sup>(1)</sup>                          | 960   | micromirrors  |
| N          | Number of active rows <sup>(1)</sup>                             | 960   | micromirrors  |
| $\epsilon$ | Micromirror (pixel) pitch—diagonal <sup>(1)</sup>                | 7.6   | $\mu\text{m}$ |
| P          | Micromirror (pixel) pitch—horizontal and vertical <sup>(1)</sup> | 10.8  | $\mu\text{m}$ |

## 5.10 Micromirror Array Physical Characteristics (続き)

| PARAMETER                       |                                           | VALUE  | UNIT              |
|---------------------------------|-------------------------------------------|--------|-------------------|
| Micromirror active array width  | $(P \times M) + (P / 2)$                  | 10.373 | mm                |
| Micromirror active array height | $(P \times N) / 2 + (P / 2)$              | 5.189  | mm                |
| Micromirror active border       | Pond of micromirrors (POM) <sup>(2)</sup> | 10     | micromirrors/side |

- (1) See [図 5-13](#).
- (2) The structure and qualities of the border around the active array includes a band of partially functional micromirrors called the POM. These micromirrors are structurally and/or electrically prevented from tilting toward the bright or ON state, but still require an electrical bias to tilt toward OFF.

### 5.10.1 Micromirror Array Physical Characteristics Diagram



**図 5-13. Micromirror Array Physical Characteristics**

## 5.11 Micromirror Array Optical Characteristics

| PARAMETER                                       | TEST CONDITIONS                 | MIN | NOM | MAX | UNIT   |
|-------------------------------------------------|---------------------------------|-----|-----|-----|--------|
| Micromirror tilt angle                          | DMD landed state <sup>(1)</sup> |     | 12  |     | degree |
| Micromirror tilt angle tolerance <sup>(2)</sup> |                                 | –1  |     | 1   | degree |
| DMD efficiency <sup>(3)</sup>                   | 420nm – 700nm                   |     | 66% |     |        |

- (1) Measured relative to the plane formed by the overall micromirror array at 25°C.
- (2) For some applications, it is critical to account for the micromirror tilt angle variation in the overall optical system design. With some optical system designs, the micromirror tilt angle variation within a device may result in perceivable non-uniformities in the light field reflected from the micromirror array. With some optical system designs, the micromirror tilt angle variation between devices may result in colorimetry variations, system efficiency variations, or system contrast variations.
- (3) DMD efficiency is measured photopically under the following conditions: 24° illumination angle, F/2.4 illumination and collection apertures, uniform source spectrum (halogen), uniform pupil illumination, the optical system is telecentric at the DMD, and the efficiency numbers are measured with 100% electronic micromirror landed duty-cycle and do not include system optical efficiency or overfill loss. This number is measured under conditions described above and deviations from these specified conditions can result in a different efficiency value in a different optical system. The factors that can influence the DMD efficiency related to system application include: light source spectral distribution and diffraction efficiency at those wavelengths (especially with discrete light sources such as LEDs or lasers), and illumination and collection apertures (F/#) and diffraction efficiency. The interaction of these system factors as well as the DMD efficiency factors that are not system dependent are described in detail in [DMD Optical Efficiency for Visible Wavelengths Application Note](#).

## 5.12 Window Characteristics

| PARAMETER                      | MIN                    | NOM | MAX | UNIT   |
|--------------------------------|------------------------|-----|-----|--------|
| Window material designation    | Corning Eagle XG       |     |     |        |
| Window refractive index        | at wavelength 546.1 nm |     |     | 1.5119 |
| Window aperture <sup>(1)</sup> | See <sup>(1)</sup>     |     |     |        |
| Illumination overfill          | See <sup>(1)</sup>     |     |     |        |

- (1) See the mechanical package ICD for details regarding the size and location of the window aperture.

## 5.13 Chipset Component Usage Specification

The DLP4621-Q1 is a component of a chipset. Reliable function and operation of the DLP4621-Q1 requires that it be used in conjunction with the TPS99001-Q1 and DLPC231-Q1, and includes components that contain or implement TI DMD control technology. TI DMD control technology consists of the TI technology and devices used for operating or controlling a DLP DMD.

### 注

TI assumes no responsibility for image quality artifacts or DMD failures caused by optical system operating conditions exceeding limits described previously.

## 6 Detailed Description

### 6.1 Overview

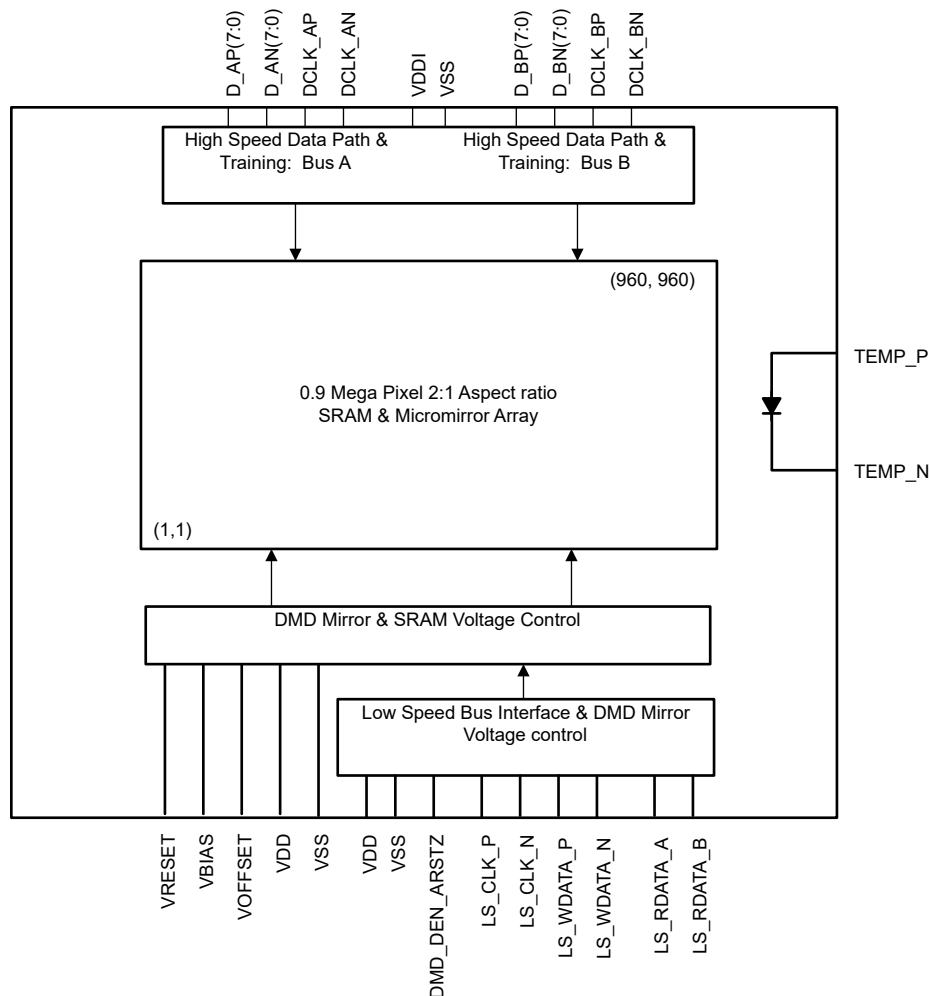
The DLP4621-Q1 automotive DMD consists of 921600 highly reflective, digitally switchable, micrometer-sized mirrors organized in a two-dimensional array. As shown in [Figure 6-13](#), the micromirror array consists of 960 micromirror columns  $\times$  960 micromirror rows in a diamond pixel configuration with a 2:1 aspect ratio.

Around the perimeter of the 960  $\times$  960 array of micromirrors is a uniform band of border micromirrors called the Pond of Micromirrors (POM). The border micromirrors are not user-addressable. The border micromirrors land in the  $-12^\circ$  position once power has been applied to the device. There are 10 border micromirrors on each side of the 960  $\times$  960 active array.

Due to the diamond pixel configuration, the columns of each odd row are offset by half a pixel from the columns of the even row. Each mirror is switchable between two discrete angular positions:  $-12^\circ$  and  $+12^\circ$ . The mirrors are illuminated from the bottom, which allows for compact and efficient system optical design.

For more information on supported resolutions and associated processing with DLPC231-Q1, refer to [DLPC230-Q1 Programmer's Guide for Light Control Applications](#).

### 6.2 Functional Block Diagram



## 6.3 Feature Description

The DLP4621-Q1 consists of a two-dimensional array of 1-bit CMOS memory cells driven by a SubLVDS bus from the DLPC231-Q1 and powered by the TPS99001-Q1. The temperature sensing diode is used to continuously monitor the DMD array temperature.

To ensure reliable operation, the DLP4621-Q1 must be used with the DLPC231-Q1 DMD display controller and the TPS99001-Q1 system management and illumination controller.

### 6.3.1 SubLVDS Data Interface

The SubLVDS signaling protocol was designed to enable very fast DMD data refresh rates while simultaneously maintaining low power and low emission.

Data is loaded into the SRAM under each micromirror using the SubLVDS interface from the DLPC231-Q1. This interface consists of 16 pairs of differential data signals plus two clock pairs into two separate buses A and B loading the left and right half of the SRAM array. The data is latched on both transitions creating a double data rate (DDR) interface. The SubLVDS interface also implements a continuous training algorithm to optimize the data and clock timing to allow for a more robust interface.

The entire DMD array of 0.9 million pixels can be updated at a rate of less than 100µs as a result of the high-speed SubLVDS interface.

### 6.3.2 Low Speed Interface for Control

The purpose of the low speed interface is to configure the DMD at power up and power down and to control the micromirror reset voltage levels that are synchronized with the data loading. The micromirror reset voltage controls the time when the mirrors are mechanically switched. The low speed differential interface includes two pairs of signals for write data and clock, and two single-ended signals for output (A and B).

### 6.3.3 DMD Voltage Supplies

The micromirrors require unique voltage levels to control the mechanical switching from  $-12^{\circ}$  to  $+12^{\circ}$ . These voltage levels are nominally 16V, 8.5V, and  $-10$ V (VBIAS, VOFFSET, and VRESET), and are generated by the TPS99001-Q1.

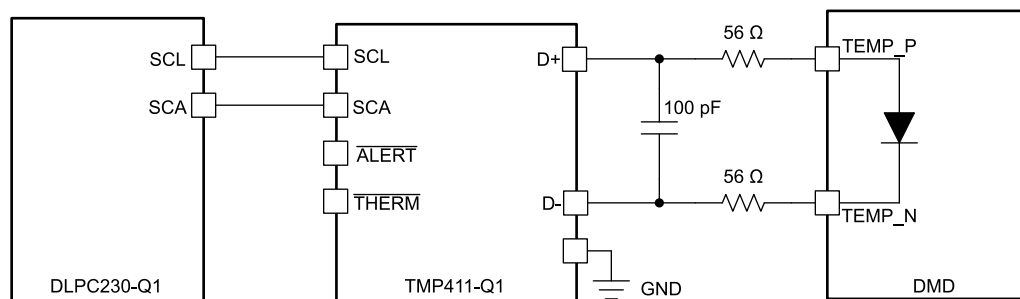
### 6.3.4 Asynchronous Reset

Reset of the DMD is required and controlled by the DLPC231-Q1 through the signal DMD\_DEN\_ARSTZ.

### 6.3.5 Temperature Sensing Diode

The DMD includes a temperature-sensing diode designed to be used with the TMP411-Q1 temperature monitoring device. The DLPC231-Q1 monitors the temperature sense diode through the TMP411-Q1. The DLPC231-Q1 operation of the DMD timing can be adjusted based on the DMD array temperature, therefore this connection is essential to ensure reliable operation of the DMD.

Figure 6-1 shows the typical connection between the DLPC231-Q1, TMP411-Q1, and the DMD.

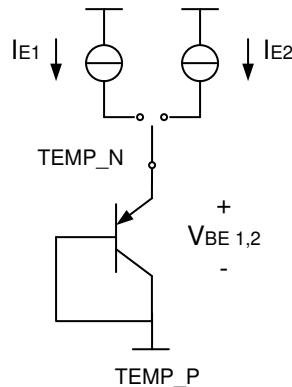


**Figure 6-1. Temperature Sense Diode Typical Circuit Configuration**

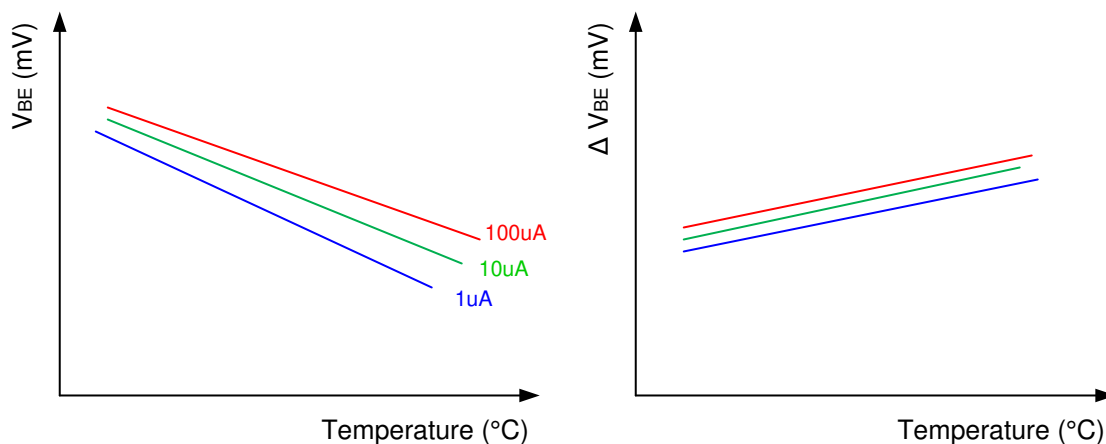
### 6.3.5.1 Temperature Sense Diode Theory

A temperature-sensing diode is based on the fundamental current and temperature characteristics of a transistor. The diode is formed by connecting the transistor base to the collector. Three different known currents flow through the diode and the resulting diode voltage is measured in each case. The difference in their base-emitter voltages is proportional to the absolute temperature of the transistor.

Refer to the [TMP411-Q1](#) data sheet for detailed information about temperature diode theory and measurement. [Figure 6-2](#) and [Figure 6-3](#) illustrate the relationships between the current and voltage through the diode.



**Figure 6-2. Temperature Measurement Theory**



**Figure 6-3. Example of Delta VBE Versus Temperature**

## 6.4 System Optical Considerations

Optimizing system optical performance and image performance strongly relates to optical system design parameter trades. Although it is not possible to anticipate every conceivable application, projector image and optical performance are contingent on compliance with the optical system operating conditions described in the following sections.

### 6.4.1 Numerical Aperture and Stray Light Control

The numerical aperture of the illumination and projection optics at the DMD optical area must be the same. This cone angle defined by the numerical aperture must not exceed the nominal device mirror tilt angle unless appropriate apertures are added in the illumination and projection pupils to block out flat-state and stray light from the projection lens. The mirror tilt angle defines the DMD's capability to separate the "On" optical path from any other light path, including undesirable flat-state specular reflections from the DMD window, DMD border structures, or other system surfaces near the DMD such as prism or lens surfaces.

### 6.4.2 Pupil Match

TI's optical and image performance specifications assume that the exit pupil of the illumination optics is nominally centered and located at the entrance pupil position of the projection optics. Misalignment of pupils between the illumination and projection optics can degrade screen image uniformity and cause objectionable artifacts in the display's border and/or active area. These artifacts may require additional system apertures to control, especially if the numerical aperture of the system exceeds the pixel tilt angle.

### 6.4.3 Illumination Overfill

Overfill light illuminating the area outside the active array can create artifacts from the mechanical features and other surfaces that surround the active array. These artifacts may be visible in the projected image. Design the illumination optical system to minimize a light flux incident outside the active array and on the window aperture. Depending on the particular system's optical architecture and assembly tolerances, this amount of overfill light on the area outside of the active array may still cause artifacts to be visible.

Illumination light and overfill can also induce undesirable thermal conditions on the DMD, especially if illumination light impinges directly on the DMD window aperture or near the edge of the DMD window. Heat load on the aperture in the areas shown in  5-1 must not exceed the values listed in [Recommended Operating Conditions](#). This area is a 0.5mm wide area and length of the aperture opening. The values listed in [Recommended Operating Conditions](#) assume a uniform distribution. For a non-uniform distribution please contact TI for additional information.

注

TI ASSUMES NO RESPONSIBILITY FOR IMAGE QUALITY ARTIFACTS OR DMD FAILURES CAUSED BY OPTICAL SYSTEM OPERATING CONDITIONS EXCEEDING LIMITS DESCRIBED PREVIOUSLY.

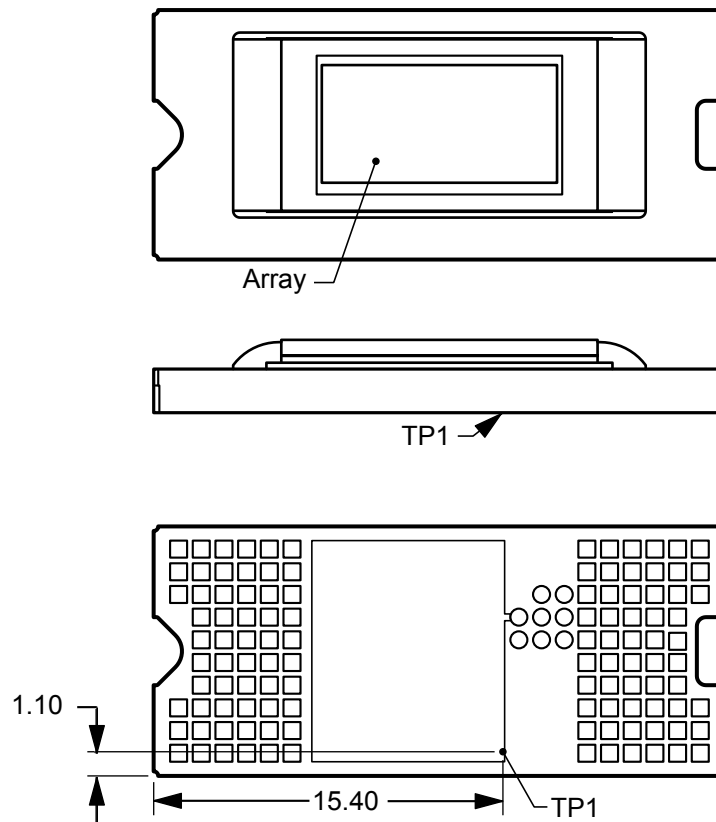
## 6.5 DMD Image Performance Specification

表 6-1. DMD Image Performance

| PARAMETER <sup>(1) (2)</sup>                                    | MIN | NOM | MAX | UNIT         |
|-----------------------------------------------------------------|-----|-----|-----|--------------|
| Dark Blemishes—Viewed on a linear blue 60 screen <sup>(3)</sup> |     |     | 4   |              |
| Light Blemishes—Viewed on a linear gray 10 screen               |     |     | 4   |              |
| Bright Pixels—Viewed on a linear gray 10 screen                 |     |     | 0   | micromirrors |
| Dark Pixels—Viewed on a white screen                            |     |     | 4   | micromirrors |

- (1) See the [System Optical Considerations](#) section.
- (2) Blemish counts do not include reflections or shadows of the same artifact. Any artifact that is not specifically called out in this table is acceptable. Viewing distance must be > 60 inches. Screen size must be similar to application image size. All values referenced are in linear gamma. Non-linear gamma curves may be running by default, and are assured by a TI applications engineer that the equivalent linear gamma value as specified is used to judge artifacts.
- (3) Linear gray 5 may be substituted in monochrome applications.

## 6.6 Micromirror Array Temperature Calculation



**図 6-4. DMD Thermal Test Points**

The active array temperature can be computed analytically from the thermal measurement point on the outside of the package, the package thermal resistance, the electrical power, and the illumination heat load. The relationship between array temperature and the reference ceramic temperature (TP1) in 図 6-4 is provided by the following equations:

$$T_{\text{ARRAY}} = T_{\text{CERAMIC}} + (Q_{\text{ARRAY}} \times R_{\text{ARRAY-TO-CERAMIC}}) \quad (1)$$

$$Q_{\text{ILLUMINATION}} = (Q_{\text{INCIDENT}} \times \text{DMD Absorption Constant}) \quad (2)$$

$$Q_{\text{ARRAY}} = Q_{\text{ELECTRICAL}} + Q_{\text{ILLUMINATION}} \quad (3)$$

where

- $T_{\text{ARRAY}}$  = computed array temperature (°C)
- $T_{\text{CERAMIC}}$  = measured ceramic temperature at the TP1 location in 図 6-4 (°C)
- $R_{\text{ARRAY-TO-CERAMIC}}$  = DMD package thermal resistance from array to thermal test point TP1 (°C/W),
- $Q_{\text{ARRAY}}$  = total power (electrical plus absorbed) on the DMD array (W)
- $Q_{\text{ELECTRICAL}}$  = nominal electrical power dissipation by the DMD (W)
- $Q_{\text{ILLUMINATION}}$  = absorbed illumination heat load (W)
- $Q_{\text{INCIDENT}}$  = incident power on the DMD (W)

The DMD absorption constant is a function of illumination distribution on the active array and the array border, angle of incidence (AOI), f number of the system, and operating state of the mirrors. The absorption constant is

higher in the OFF state than in the ON state. Equations to calculate the absorption constant are provided for both ON and OFF mirror states. They assume an AOI of 34 degrees, an f/1.7 system, and they account for the distribution of light on the active array, POM, and array border.

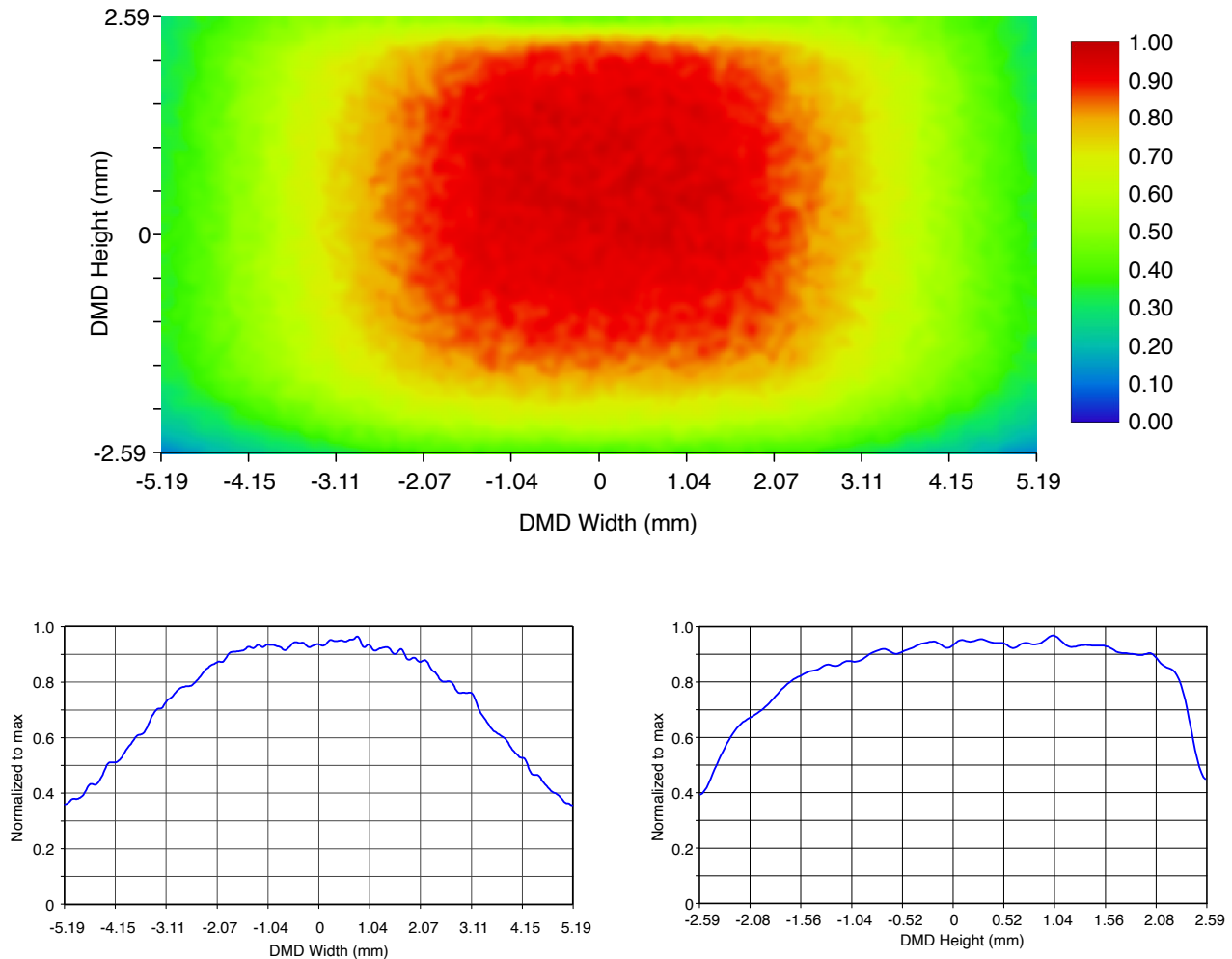
$$\text{DMD Absorption Constant (OFF state)} = 0.895 - 0.004783 \times (\% \text{ of light on ActiveArray} + \text{POM}) \quad (4)$$

$$\text{DMD Absorption Constant (ON state)} = 0.895 - 0.007208 \times (\% \text{ of light on ActiveArray} + \text{POM}) \quad (5)$$

Electrical power dissipation of the DMD is variable and depends on the voltages, data rates, and operating frequencies.

The DMD package thermal resistance from array to ceramic ( $R_{\text{ARRAY-TO-CERAMIC}}$ ) assumes a non-uniform illumination distribution on the DMD as shown in [Non-Uniform Illumination Profile](#) figure. For illumination profiles more uniform than the one highlighted in [Non-Uniform Illumination Profile](#) figure, the value provided here is valid.

However, for more non-uniform profiles (for example, Gaussian distribution) the thermal resistance will be higher. Please contact TI to determine an accurate value for this case.



**図 6-5. Non-Uniform Illumination Profile**

The following sample calculations assume 10% of the total incident light falls outside of the active array and POM, and the mirrors are in the OFF state.

1.  $T_{\text{CERAMIC}} = 50^{\circ}\text{C}$  (measured)
2.  $Q_{\text{INCIDENT}} = 10\text{W}$  (measured)

3. DMD Absorption Constant =  $0.895 - 0.004783 \times 90 = 0.46$
4.  $Q_{\text{ELECTRICAL}} = 0.4\text{W}$
5.  $R_{\text{ARRAY-TO-CERAMIC}} = 1.5^{\circ}\text{C/W}$
6.  $Q_{\text{ARRAY}} = 0.4\text{W} + (0.46 \times 10\text{ W}) = 5\text{W}$
7.  $T_{\text{ARRAY}} = 50^{\circ}\text{C} + (5\text{W} \times 1.5^{\circ}\text{C/W}) = 57.5^{\circ}\text{C}$

When designing the DMD heatsink solution, the package thermal resistance from array to reference ceramic temperature (thermocouple location TP1 can be used to determine the temperature rise through the package as given by the following equations:

$$T_{\text{ARRAY-TO-CERAMIC}} = Q_{\text{ARRAY}} \times R_{\text{ARRAY-TO-CERAMIC}} \quad (6)$$

### 6.6.1 Monitoring Array Temperature Using the Temperature Sense Diode

The active array temperature can be computed analytically from the temperature sense diode measurement, the thermal resistance from array to diode, the electrical power, and the illumination heat load. The relationship between array temperature and the temperature sense diode is provided by the following equations:

$$T_{\text{ARRAY}} = T_{\text{DIODE}} + (Q_{\text{ARRAY}} \times R_{\text{ARRAY-TO-DIODE}}) \quad (7)$$

$$Q_{\text{ILLUMINATION}} = (Q_{\text{INCIDENT}} \times \text{DMD Absorption Constant}) \quad (8)$$

$$Q_{\text{ARRAY}} = Q_{\text{ELECTRICAL}} + Q_{\text{ILLUMINATION}} \quad (9)$$

where

- $T_{\text{ARRAY}}$  = computed array temperature ( $^{\circ}\text{C}$ )
- $T_{\text{DIODE}}$  = measured temperature sense diode temperature ( $^{\circ}\text{C}$ )
- $R_{\text{ARRAY-TO-DIODE}}$  = package thermal resistance from array to diode ( $^{\circ}\text{C/W}$ )
- $Q_{\text{ARRAY}}$  = total power, electrical plus absorbed, on the DMD array (W)  
Refer to [Section 7.6](#) for details.
- $Q_{\text{ELECTRICAL}}$  = nominal electrical power dissipation by the DMD (W)
- $Q_{\text{ILLUMINATION}}$  = absorbed illumination heat load (W)
- $Q_{\text{INCIDENT}}$  = incident power on the DMD (W)

The temperature sense diode to array thermal resistance ( $R_{\text{ARRAY-TO-DIODE}}$ ) assumes a non-uniform illumination distribution on the DMD as shown in *Non-Uniform Illumination Profile*. For illumination profiles more uniform than the one highlighted in *Non-Uniform Illumination Profile*, the value provided here is valid. However, for more non-uniform profiles (for example, Gaussian distribution), the thermal resistance will be higher. Please contact TI to determine an accurate value for this case.

The following sample calculations assume 10% of the total incident light falls outside of the active array and POM, and the mirrors are in the OFF state.

1.  $T_{\text{DIODE}} = 54^{\circ}\text{C}$
2.  $Q_{\text{INCIDENT}} = 10\text{W}$  (measured)
3. DMD Absorption Constant =  $0.895 - 0.004783 \times 90 = 0.46$
4.  $Q_{\text{ELECTRICAL}} = 0.4\text{W}$
5.  $R_{\text{ARRAY-TO-DIODE}} = 0.5^{\circ}\text{C/W}$
6.  $Q_{\text{ARRAY}} = 0.4\text{W} + (0.46 \times 10\text{W}) = 5\text{W}$
7.  $T_{\text{ARRAY}} = 54^{\circ}\text{C} + (5\text{ W} \times 0.5^{\circ}\text{C/W}) = 56.5^{\circ}\text{C}$

## 6.7 Micromirror Landed-On/Landed-Off Duty Cycle

### 6.7.1 Definition of Micromirror Landed-On/Landed-Off Duty Cycle

The micromirror landed-on/landed-off duty cycle (landed duty cycle) denotes the amount of time (as a percentage) that an individual micromirror is landed in the ON state versus the amount of time the same micromirror is landed in the OFF state.

As an example, a landed duty cycle of 90/10 indicates that the referenced pixel is in the ON state 90% of the time (and in the OFF state 10% of the time), whereas 10/90 would indicate that the pixel is in the OFF state 90% of the time. Likewise, 50/50 indicates that the pixel is ON 50% of the time and OFF 50% of the time.

Note that when assessing landed duty cycle, the time spent switching from one state (ON or OFF) to the other state (OFF or ON) is considered negligible and is thus ignored.

Since a micromirror can only be landed in one state or the other (ON or OFF), the two numbers (percentages) always add to 100.

## 7 Application and Implementation

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### 注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

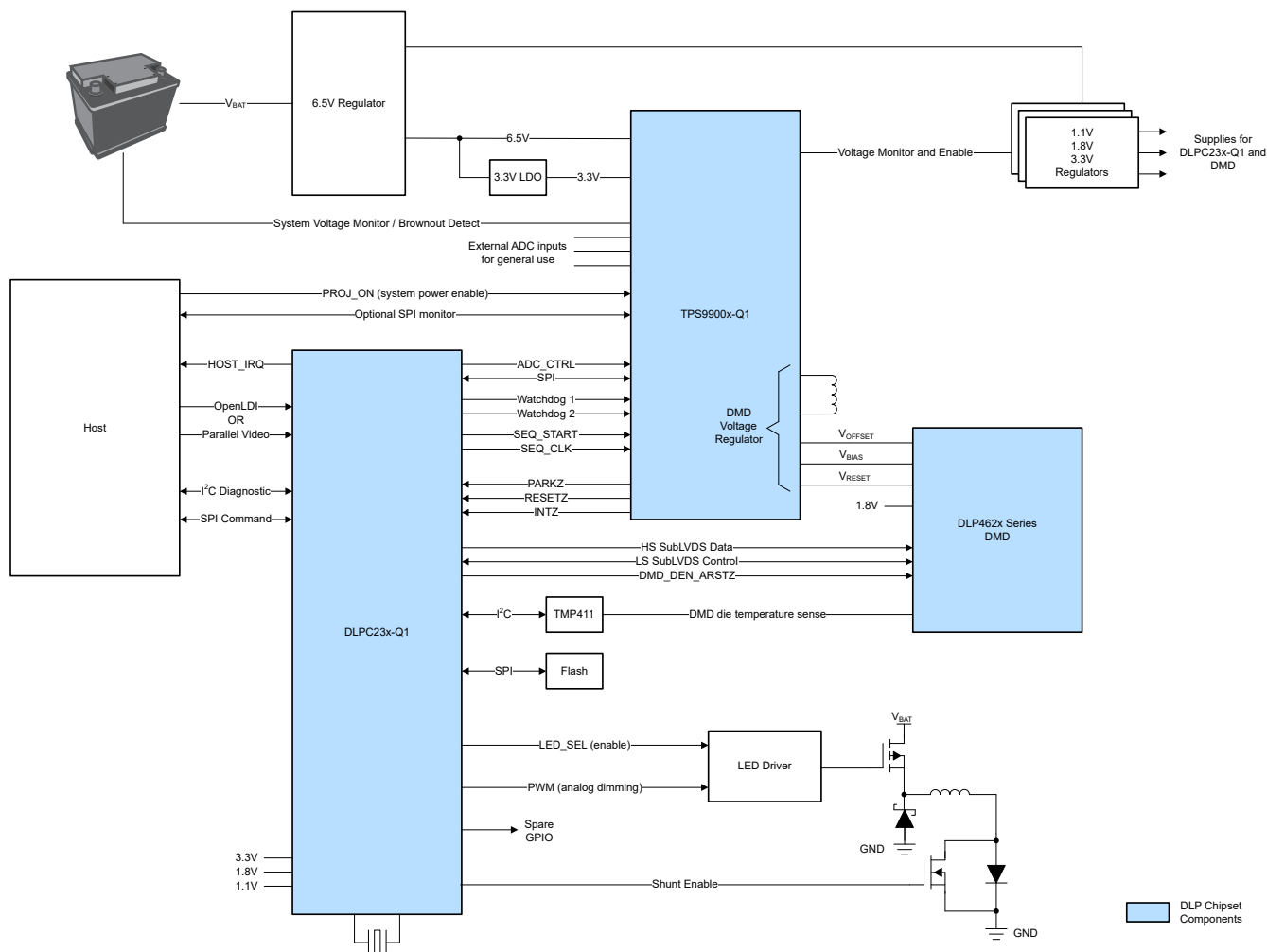
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### 7.1 Application Information

The DLP4621-Q1 chipset is designed to support projection-based automotive applications such as high-resolution adaptive driving beam (ADB) headlights.

### 7.2 Typical Application

The chipset consists of three components—the DLP4621-Q1 automotive DMD, the DLPC231-Q1, and the TPS99001-Q1. The DMD is a light modulator consisting of tiny mirrors that are used to form and project images. The DLPC231-Q1 is a controller for the DMD; it formats incoming video and controls the timing of the DMD illumination sources and the DMD in order to display the incoming video. The TPS99001-Q1 is a high-performance voltage regulator for the DMD and a management IC for the entire chipset. In conjunction, the DLPC231-Q1 and the TPS99001-Q1 can be used for system-level monitoring, diagnostics, and failure detection features.  7-1 is a system-level block diagram with these devices in the DLP headlight module configuration and displays the primary features and functions of each device.



**7-1. Headlight System Block Diagram**

### 7.2.1 Application Overview

☒ 7-1 shows the system block diagram for a DLP headlight module. The system uses the DLPC231-Q1, TPS99001-Q1, and the DLP4621-Q1 automotive DMD to enable a headlight projection system with unprecedented resolution and grayscale light control. The combination of the DLPC231-Q1 and TPS99001-Q1 removes the need for external SDRAM and a dedicated microprocessor. The chipset manages the illumination control of LED sources, power sequencing functions, and system management functions. Additionally, the chipset supports numerous system diagnostic and built-in self-test (BIST) features. The following paragraphs describe the functionality of the chipset used for a headlight projection system in more detail.

The DLPC231-Q1 is a controller for the DMD and the light sources in the DLP Headlight, HUD or Projector module. It receives input video from the host and synchronizes DMD and light source timing to achieve the desired video. The DLPC231-Q1 formats input video data that is displayed on the DMD. It synchronizes these video segments with light source timing in order to create a video with grayscale shading and multiple colors, if applicable.

The DLPC231-Q1 receives inputs from a host processor in the vehicle. The host provides commands and input video data. Host commands can be sent using either the I<sup>2</sup>C bus or SPI bus. The bus that is not being used for host commands can be used as a read-only bus for diagnostic purposes. Input video can be sent over an OpenLDI bus or a parallel 24-bit bus. The 24-bit bus can be limited to only 8-bits or 16-bits of data for single light source or dual light source systems depending on the system design. The SPI flash memory provides the embedded software for the DLPC231-Q1's ARM core, any calibration data, and default settings. The TPS99001-Q1 provides diagnostic and monitoring information to the DLPC231-Q1 using an SPI bus and several other control signals such as PARKZ, INTZ, and RESETZ to manage power-up and power-down sequencing. The TMP411 uses an I<sup>2</sup>C interface to provide the DMD array temperature to the DLPC231-Q1.

The outputs of the DLPC231-Q1 are configuration and monitoring commands to the TPS99001-Q1, timing controls to the LED or laser driver, control and data signals to the DMD, and monitoring and diagnostics information to the host processor. The DLPC231-Q1 communicates with the TPS99001-Q1 over an SPI bus. It uses this to configure the TPS99001-Q1 and to read monitoring and diagnostics information from the TPS99001-Q1. The DLPC231-Q1 sends drive-enable signals to the LED or laser driver, and synchronizes this with the DMD mirror timing. The control signals to the DMD are sent using a SubLVDS interface.

The TPS99001-Q1 is a highly integrated mixed-signal IC that controls DMD power and provides monitoring and diagnostics information for the DLP headlight module. The power sequencing and monitoring blocks of the TPS99001-Q1 properly power up the DMD and provide accurate DMD voltage rails (–16V, 8.5V, and 10V), and then monitor the system's power rails during operation. The integration of these functions into one IC significantly reduces design time and complexity. The TPS99001-Q1 also has several output signals that can be used to control a variety of LED or laser driver topologies. The TPS99001-Q1 has several general-purpose ADCs that designers can use for system-level monitoring, such as over-brightness detection.

The TPS99001-Q1 receives inputs from the DLPC231-Q1, the power rails it monitors, the host processor, and potentially several other ADC ports. The DLPC231-Q1 sends configuration and control commands to the TPS99001-Q1 over an SPI bus and several other control signals. The DLPC231-Q1's clocks are also monitored by the watchdogs in the TPS99001-Q1 to detect any errors. The power rails are monitored by the TPS99001-Q1 in order to detect power failures or glitches and request a proper power down of the DMD in case of an error. The host processor can read diagnostics information from the TPS99001-Q1 using a dedicated SPI bus, which enables independent monitoring. Additionally, the host can request the image to be turned on or off using a PROJ\_ON signal. Lastly, the TPS99001-Q1 has several general-purpose ADCs that can be used to implement system-level monitoring functions.

The outputs of the TPS99001-Q1 are diagnostic information and error alerts to the DLPC231-Q1, and control signals to the LED or laser driver. The TPS99001-Q1 can output diagnostic information to the host and the DLPC231-Q1 over two SPI buses. In case of critical system errors, such as power loss, it outputs signals to the DLPC231-Q1 that trigger power down or reset sequences. It also has output signals that can be used to implement various LED or laser driver topologies.

The DMD is a micro-electro-mechanical system (MEMS) device that receives electrical signals as an input (video data), and produces a mechanical output (mirror position). The electrical interface to the DMD is a SubLVDS interface with the DLPC231-Q1. The mechanical output is the state of more than 0.9 million mirrors in the DMD array that can be tilted  $\pm 12^\circ$ . In a projection system the mirrors are used as pixels to display an image.

### 7.2.2 Input Image Resolution

The DLP4621-Q1 together with the DLPC231-Q1 supports different display resolutions, some include diamond down sampling (DDS). For information on how the input image is displayed onto the DLP4621-Q1 and DDS function, refer to the [DLPC230-Q1 Programmer's Guide for Light Control Applications](#).

### 7.2.3 Reference Design

For information about connecting together the DLP4621-Q1 DMD, DLPC231-Q1 controller, and TPS99001-Q1, contact the TI Application Team for additional information about the DLP4621-Q1 evaluation module (EVM). TI has optical-mechanical reference designs available, see the TI Application team for more information.

### 7.2.4 Application Mission Profile Consideration

Each application is anticipated to have different mission profiles, or number of operating hours at different temperatures. To assist in evaluation an Application Report may be provided in the future. See the TI Application team for more information.

## 7.3 Power Supply Recommendations

The following power supplies are all required to operate the DMD: VDD, VDDI, VOFFSET, VBIAS, and VRESET. All VSS connections are also required. DMD power-up and power-down sequencing is strictly controlled by the TPS99001-Q1 device.

#### 注意

For reliable operation of the DMD, the following power supply sequencing requirements must be followed. Failure to adhere to the prescribed power-up and power-down procedures may affect device reliability.

VDD, VDDI, VOFFSET, VBIAS, and VRESET power supplies have to be coordinated during power-up and power-down operations. Failure to meet any of the below requirements will result in a significant reduction in the DMD's reliability and lifetime. VSS must also be connected.

### 7.3.1 Power Supply Power-Up Procedure

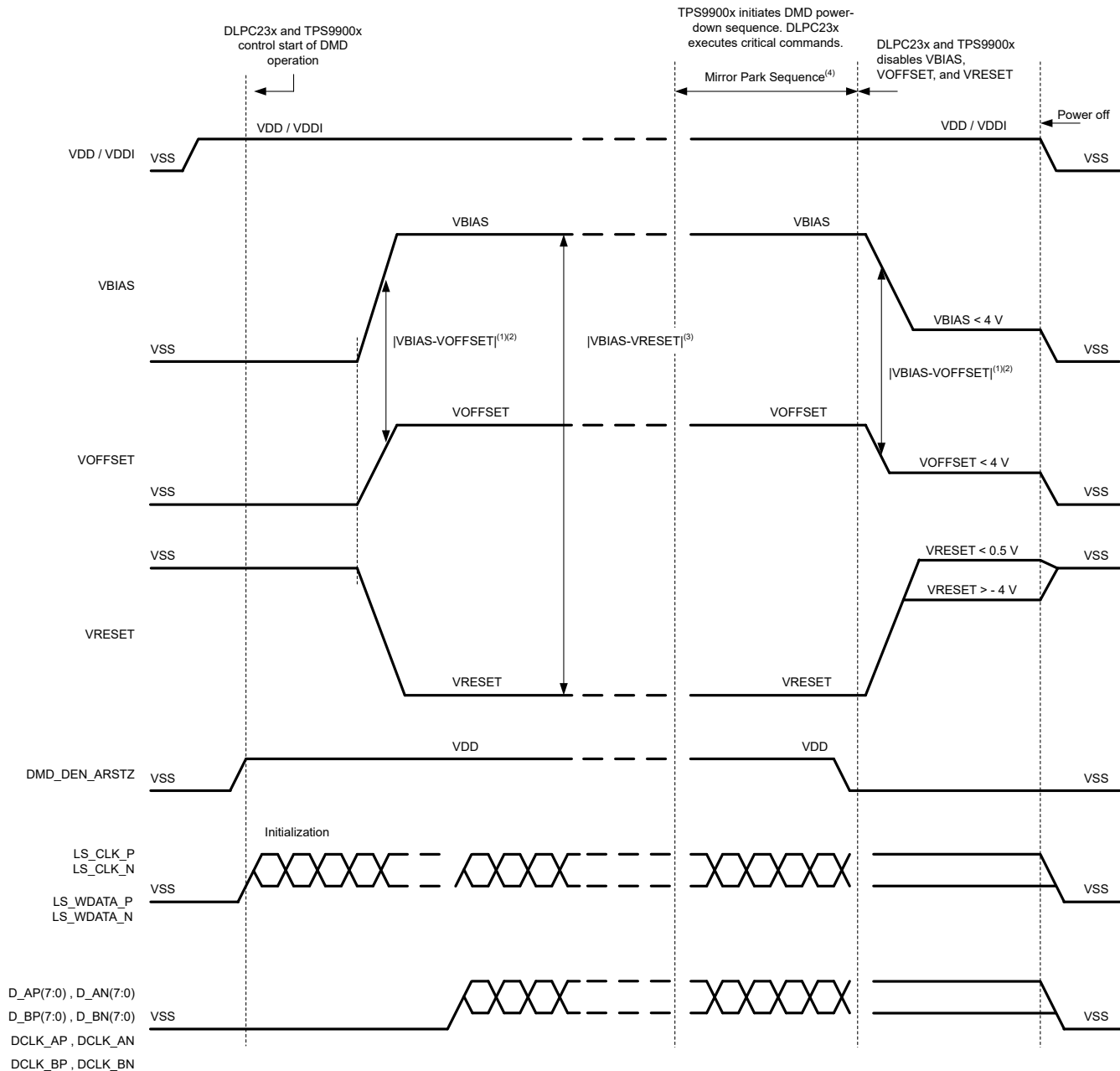
- During power-up, VDD and VDDI must always start and settle before VOFFSET, VBIAS, and VRESET voltages are applied to the DMD.
- During power-up, it is a strict requirement that the delta between VBIAS and VOFFSET must be within the specified limit shown in the [Recommended Operating Conditions](#).
- During power-up, the DMD's LPSDR input pins shall not be driven high until after VDD and VDDI have settled at operating voltage.
- During power-up, there is no requirement for the relative timing of VRESET with respect to VOFFSET and VBIAS. Power supply slew rates during power-up are flexible, provided that the transient voltage levels follow the requirements listed previously and in [Figure 7-2](#).

### 7.3.2 Power Supply Power-Down Procedure

- The power-down sequence is the reverse order of the previous power-up sequence. VDD and VDDI must be supplied until after VBIAS, VRESET, and VOFFSET are discharged to within 4V of ground.
- During power-down, it is not mandatory to stop driving VBIAS prior to VOFFSET, but it is a strict requirement that the delta between VBIAS and VOFFSET must be within the specified limit shown in the [Recommended Operating Conditions](#).
- During power-down, the DMD's LPSDR input pins must be less than VDDI, the specified limit shown in the [Recommended Operating Conditions](#).

- During power-down, there is no requirement for the relative timing of VRESET with respect to VOFFSET and VBIAS.
- Power supply slew rates during power-down are flexible, provided that the transient voltage levels follow the requirements listed previously and in the *Power Supply Sequencing Requirements (Power Up and Power Down)* graphic.

### 7.3.3 Power Supply Sequencing Requirements



1. To prevent excess current, the supply voltage delta  $|VBIAS - VOFFSET|$  must be less than specified in the [Recommended Operating Conditions](#). OEMs may find that the most reliable way to ensure this is to power VOFFSET prior to VBIAS during power-up and to remove VBIAS prior to VOFFSET during power-down. Also, the TPS99001-Q1 is capable of managing the timing between VBIAS and VOFFSET.
2. To prevent excess current, the supply voltage delta  $|VBIAS - VRESET|$  must be less than specified than the limit shown in the [Recommended Operating Conditions](#).

3. When system power is interrupted, the TPS99001-Q1 initiates hardware power-down that disables VBIAS, VRESET, and VOFFSET after the Micromirror Park Sequence.
4. LS\_CLK and LS\_WDATA signals are ignored until DMD\_DEN\_ARSTZ is released.
5. The drawing is not to scale and details are omitted for clarity. For example, the DLPC231-Q1 will read information from DLP4621-Q1 during initialization and activity on LS\_CLK, LS\_WDATA, and DMD\_DEN\_ARSTZ may toggle multiple times prior to displaying information on DLP4621-Q1.

## 7-2. Power Supply Sequencing Requirements (Power Up and Power Down)

### 7.4 Layout Guidelines

Refer to the DLPC231-Q1 and TPS99001-Q1 data sheets for specific PCB layout and routing guidelines. For specific DMD PCB guidelines, use the following:

- Match lengths for the LS\_WDATA and LS\_CLK signals
- Minimize vias, layer changes, and turns for the HS bus signals
- Minimum of two 220nF decoupling capacitors close to VBIAS
- Minimum of two 220nF decoupling capacitors close to VRESET
- Minimum of three 4.7μF decoupling capacitors close to VOFFSET
- Minimum of four 100nF decoupling capacitors close to VDDI and VDD
- Temperature diode pins

The DMD has an internal diode (PN junction) that is intended to be used with an external TI TMP411 temperature sensing IC. PCB traces from the DMD's temperature diode pins to the TMP411 are sensitive to noise. See the [TMP411 ±1°C Remote and Local Temperature Sensor with N-Factor and Series Resistance Correction Data Sheet](#) for specific routing recommendations.

### 7.5 Layout Example

The DLP4621-Q1 example layouts are shown for high-speed SubLVDS pairs and the micromirror voltage supplies (VBIAS, VOFFSET, and VRESET). The 1.8V power supplies must have a dedicated power plane.

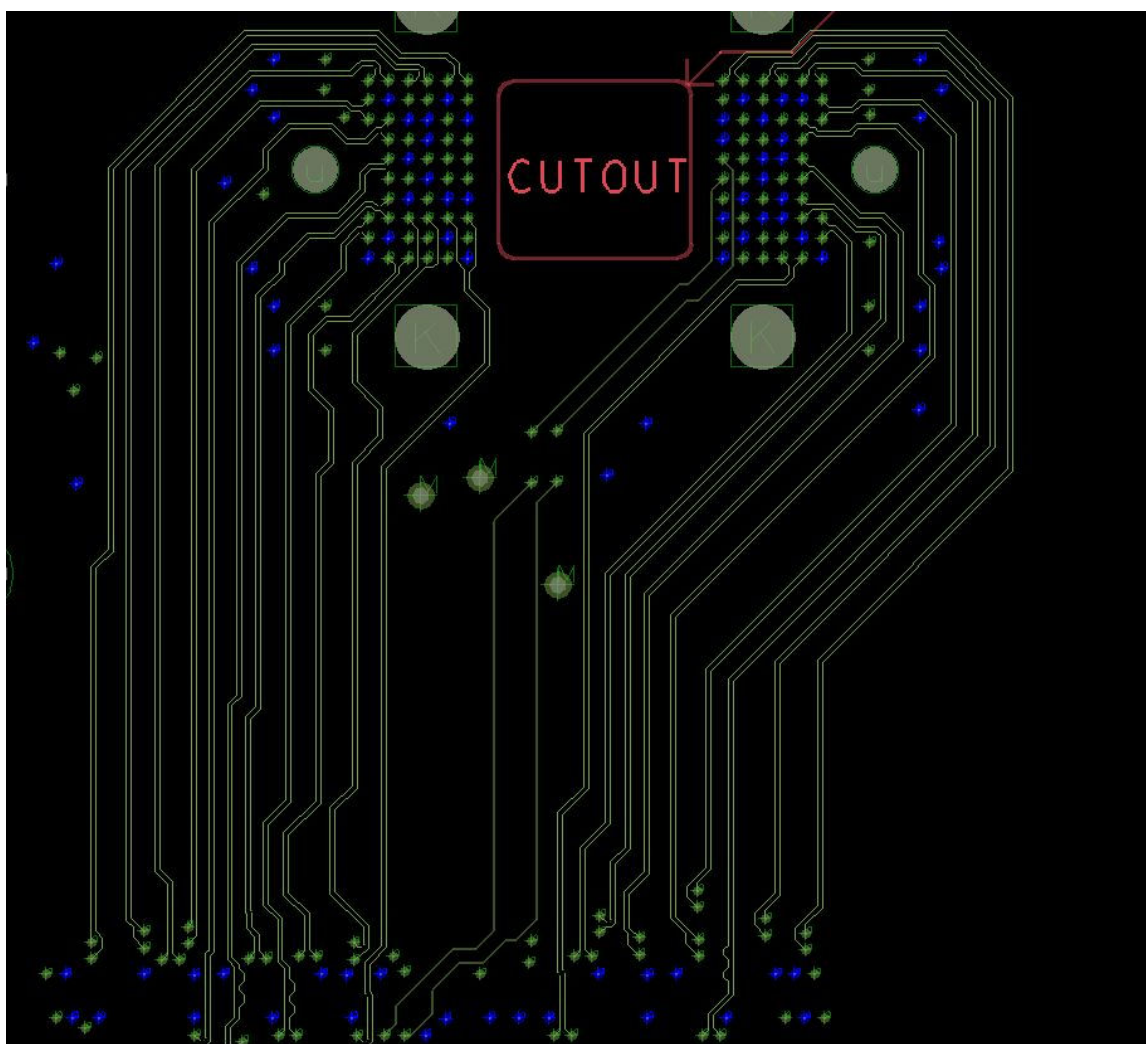
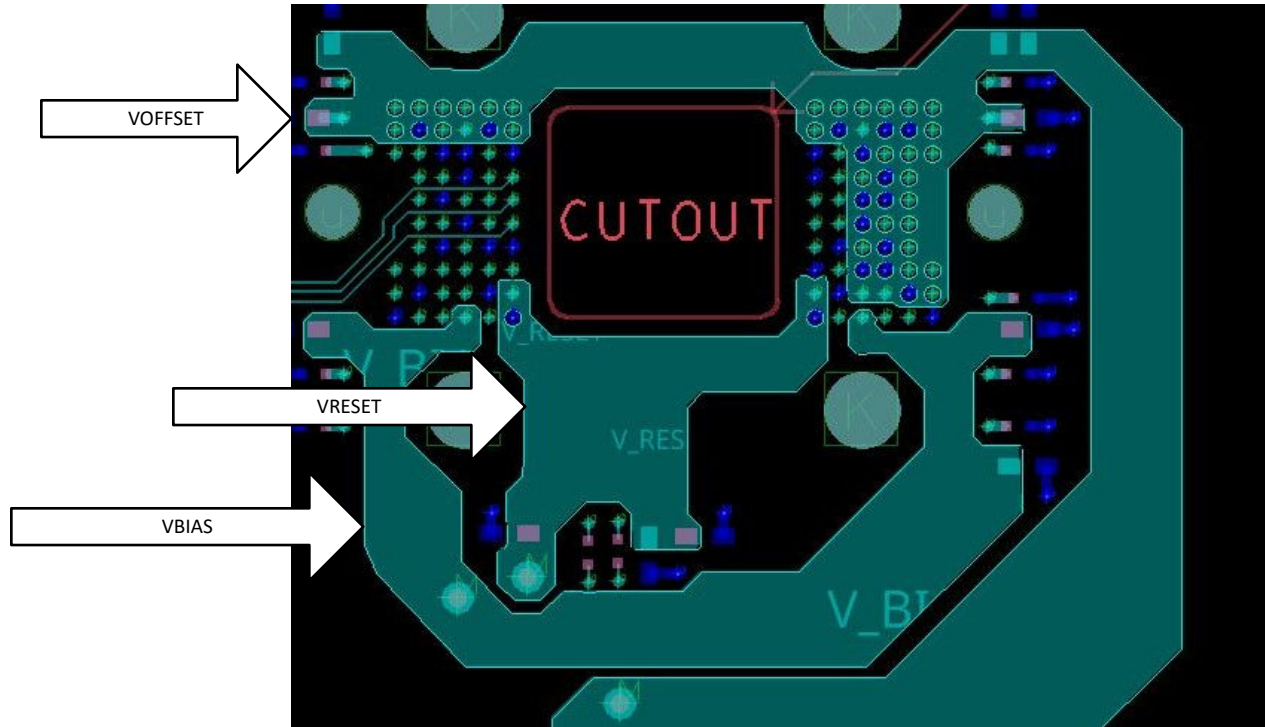


図 7-3. High Speed SubLVDS Pairs




**7-4. DMD Micromirror Supply Voltages (VBIAS, VOFFSET, and VRESET)**

## 8 Device and Documentation Support

### 8.1 Device Support

#### 8.1.1 Device Nomenclature

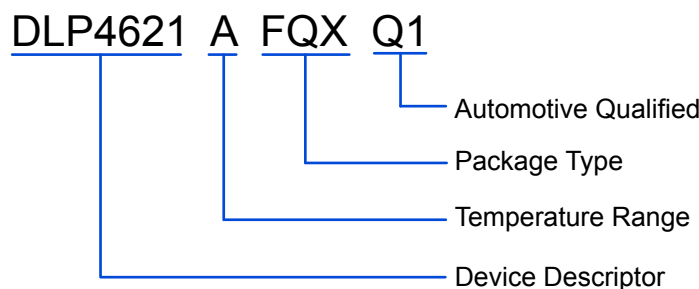


図 8-1. Part Number Description

#### 8.1.2 Device Markings

The device marking includes the legible character string GHJJJK DLP4621AFQXQ1. GHJJJK is the lot trace code. DLP4621AFQXQ1 is the part number.

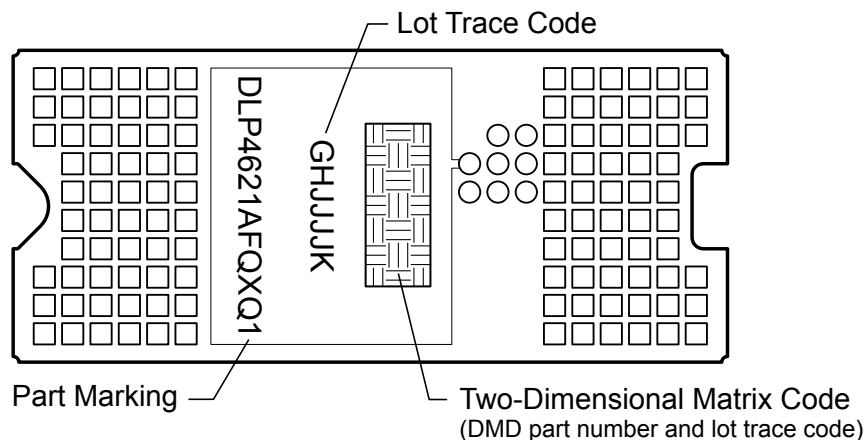


図 8-2. DMD Marking

### 8.2 サード・パーティ製品に関する免責事項

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### 8.3 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[www.tij.co.jp](http://www.tij.co.jp) のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

## 8.4 サポート・リソース

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## 8.5 Trademarks

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DLP® is a registered trademark of Texas Instruments.

すべての商標は、それぞれの所有者に帰属します。

## 8.6 静電気放電に関する注意事項



この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うことを推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

## 8.7 DMD Handling

The DMD is an optical device so take precautions to avoid damaging the glass window. See the application note [DLPA019 DMD Handling](#) for instructions on how to properly handle the DMD.

## 8.8 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

## 9 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

| Changes from Revision A (February 2024) to Revision B (August 2024)                                                        | Page |
|----------------------------------------------------------------------------------------------------------------------------|------|
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| • Updated the clock frequency, DCLK, for the high-speed interface in <a href="#">Timing Requirements</a> .....             | 11   |

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## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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## PACKAGING INFORMATION

| Orderable part number         | Status<br>(1) | Material type<br>(2) | Package   Pins   | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-------------------------------|---------------|----------------------|------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">DLP4621AFQXQ1</a> | Active        | Production           | CLGA (FQX)   120 | 72   JEDEC TRAY (5+1) | Yes         | Call TI                              | N/A for Pkg Type                  | -40 to 105   |                     |
| DLP4621AFQXQ1.A               | Active        | Production           | CLGA (FQX)   120 | 72   JEDEC TRAY (5+1) | Yes         | Call TI                              | N/A for Pkg Type                  | -40 to 105   |                     |
| DLP4621AFQXQ1.B               | Active        | Production           | CLGA (FQX)   120 | 72   JEDEC TRAY (5+1) | -           | Call TI                              | Call TI                           | -40 to 105   |                     |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

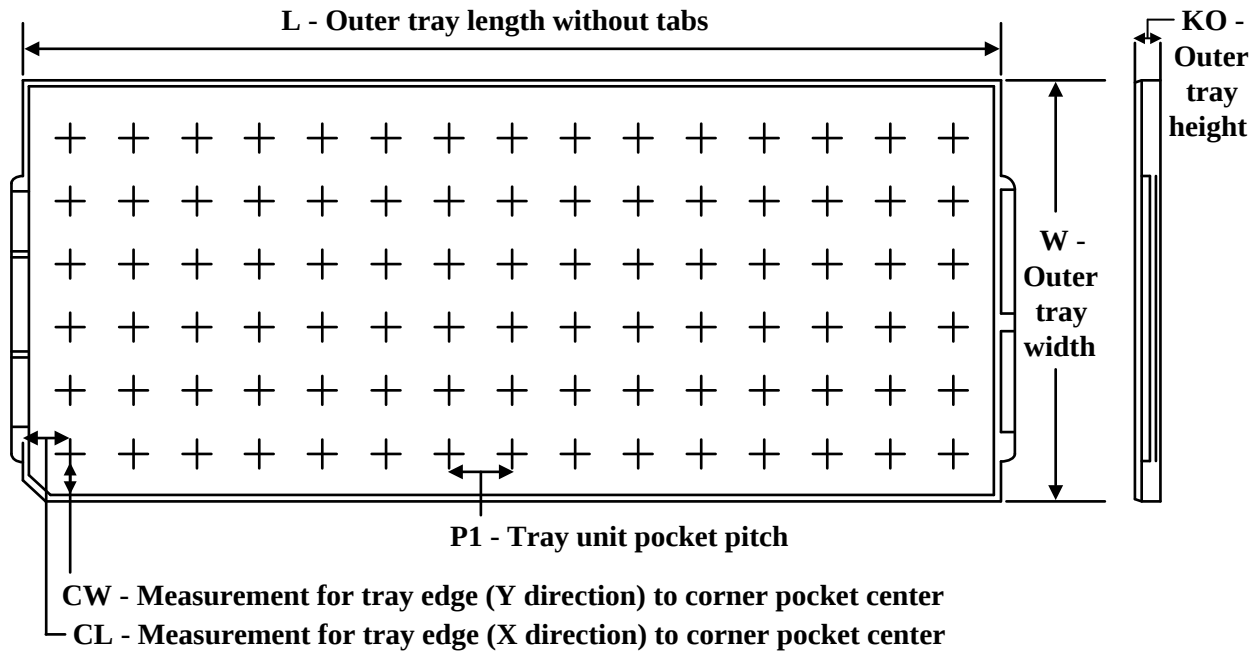
<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TRAY



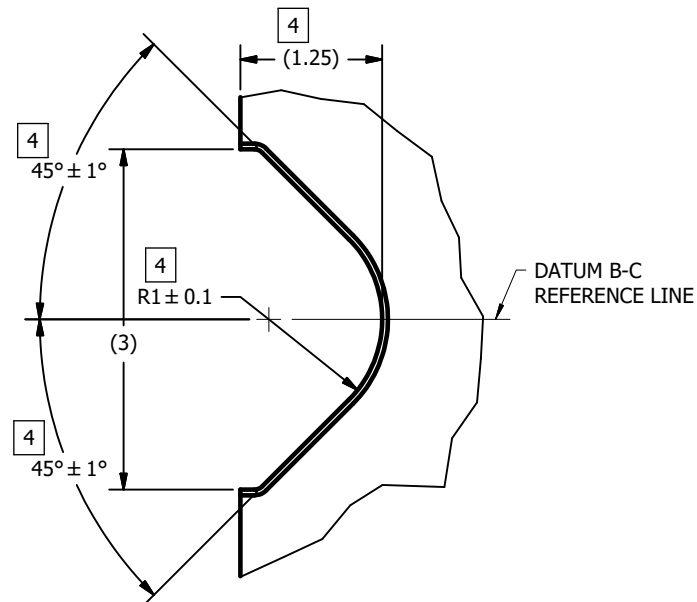
Chamfer on Tray corner indicates Pin 1 orientation of packed units.

\*All dimensions are nominal

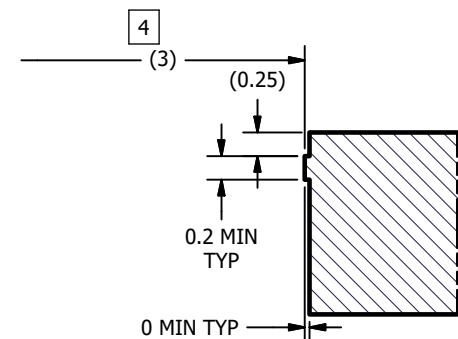
| Device          | Package Name | Package Type | Pins | SPQ | Unit array matrix | Max temperature (°C) | L (mm) | W (mm) | K0 (µm) | P1 (mm) | CL (mm) | CW (mm) |
|-----------------|--------------|--------------|------|-----|-------------------|----------------------|--------|--------|---------|---------|---------|---------|
| DLP4621AFQXQ1   | FQX          | CLGA         | 120  | 72  | 8 x 7             | 150                  | 315    | 135.9  | 12190   | 21.9    | 15.15   | 16.95   |
| DLP4621AFQXQ1.A | FQX          | CLGA         | 120  | 72  | 8 x 7             | 150                  | 315    | 135.9  | 12190   | 21.9    | 15.15   | 16.95   |

- 1 DIE PARALLELISM TOLERANCE APPLIES TO DMD ACTIVE ARRAY ONLY.
- 2 ROTATION ANGLE OF DMD ACTIVE ARRAY IS A REFINEMENT OF THE LOCATION TOLERANCE AND HAS A MAXIMUM ALLOWED VALUE OF 0.6 DEGREES.
- 3 BOUNDARY MIRRORS SURROUNDING THE DMD ACTIVE ARRAY.
- 4 NOTCH DIMENSIONS ARE DEFINED BY SECOND LAYER OF CERAMIC, AS SHOWN IN SECTION A-A.
- 5 ENCAPSULANT TO BE CONTAINED WITHIN DIMENSIONS SHOWN IN VIEW D (SHEET 3). NO ENCAPSULANT IS ALLOWED ON TOP OF THE WINDOW.
- 6 ENCAPSULANT NOT TO EXCEED THE HEIGHT OF THE WINDOW.
- 7 SEE DETAIL B FOR "V-NOTCH" DIMENSIONS.
- 8 WHILE ONLY THE THREE DATUM A TARGET AREAS A1, A2, AND A3 ARE USED FOR MEASUREMENT, ALL 4 CORNERS SHOULD BE CONTACTED, INCLUDING E1, TO SUPPORT MECHANICAL LOADS.
- 9 SHORTING TEST PADS AND SYMBOLIZATION PAD TO EACH OTHER AND/OR TO VSS IS ACCEPTABLE.

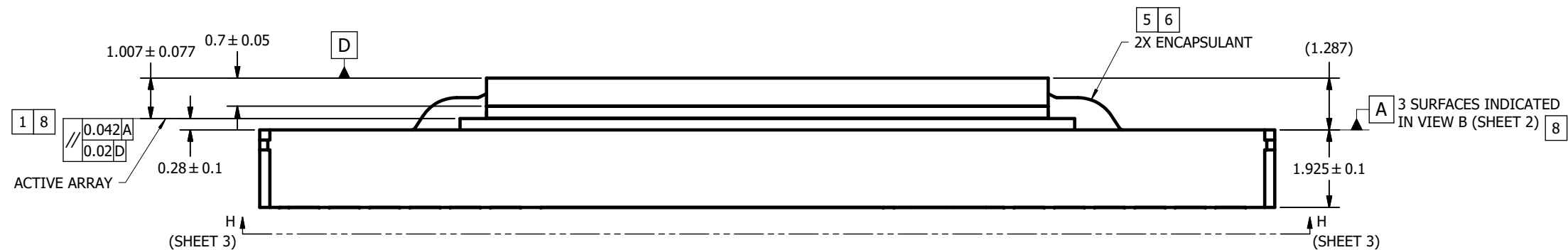
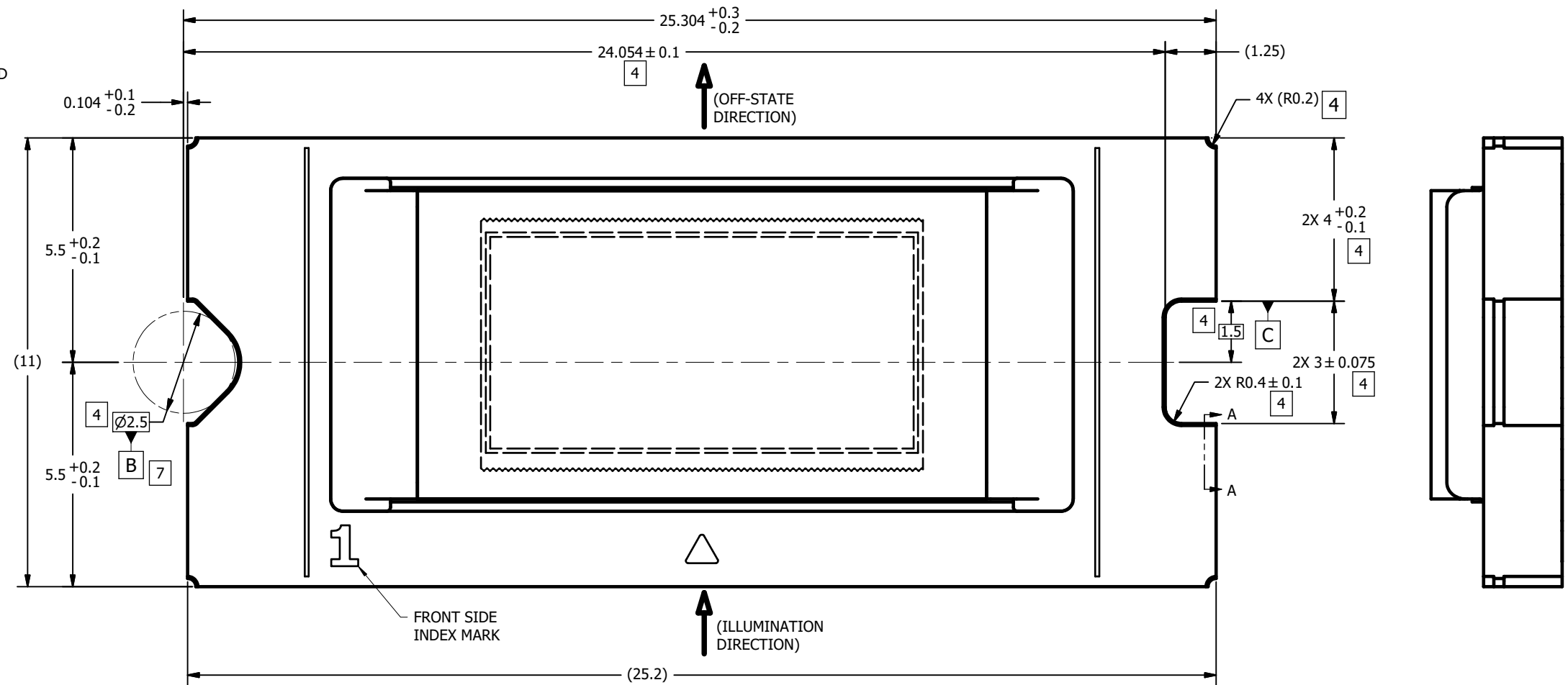
| REVISIONS |                                                                                               |           |     |
|-----------|-----------------------------------------------------------------------------------------------|-----------|-----|
| REV       | DESCRIPTION                                                                                   | DATE      | BY  |
| A         | ECO 2199615: INITIAL RELEASE                                                                  | 4/19/2022 | BMH |
| B         | ECO 2200854: TOLERANCE RIGHT & BOTTOM EDGES FROM DATUMS B/C, INSTEAD OF FROM LEFT & TOP EDGES | 8/1/2022  | BMH |



DETAIL B  
V-NOTCH  
SCALE 30 : 1



SECTION A-A  
NOTCH OFFSETS  
SCALE 25 : 1  
(ROTATED 90°)



UNLESS OTHERWISE SPECIFIED

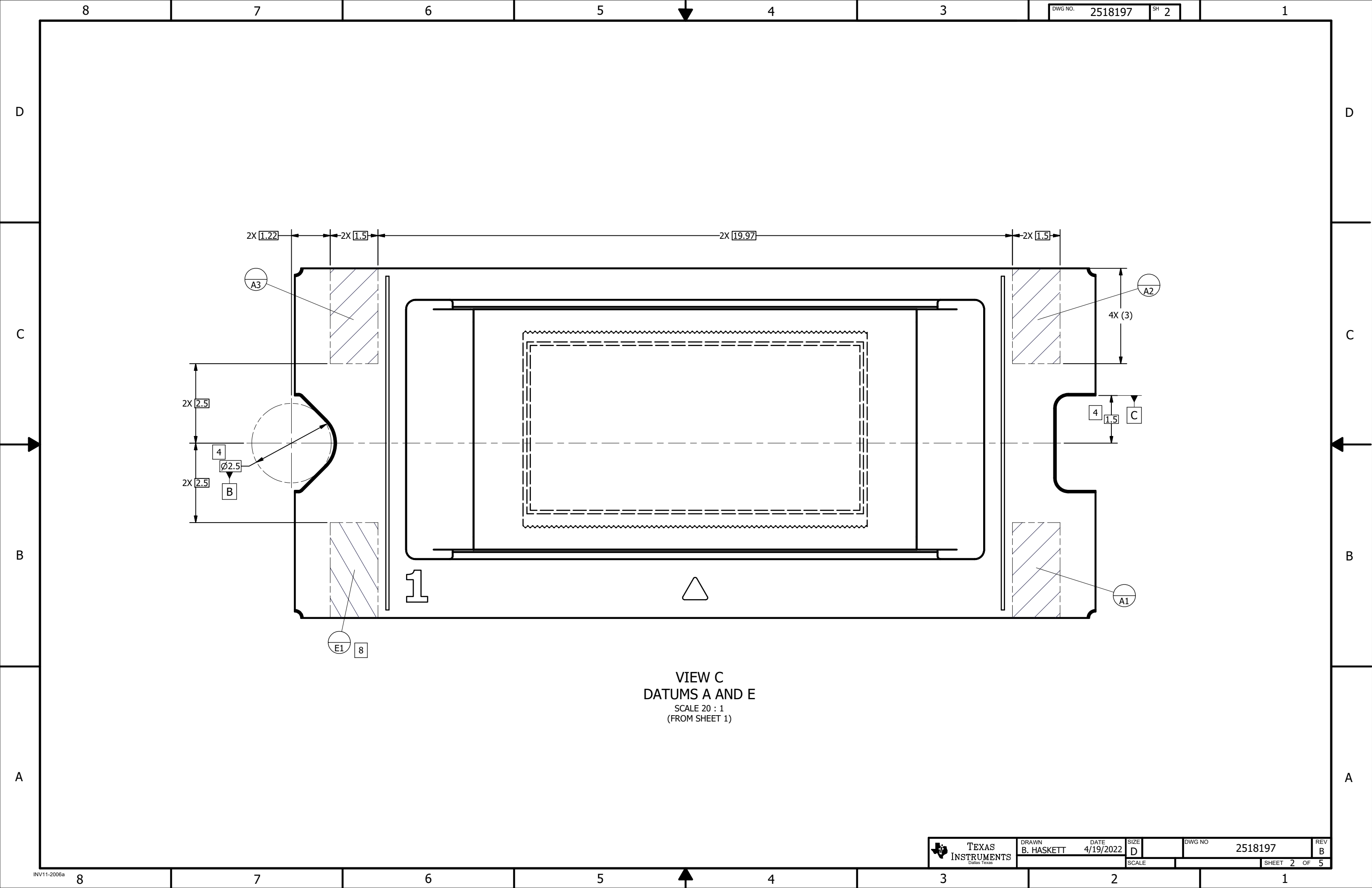
- DIMENSIONS ARE IN MILLIMETERS
- TOLERANCES:  
ANGLES  $\pm 1^\circ$   
2 PLACE DECIMALS  $\pm 0.25$   
1 PLACE DECIMALS  $\pm 0.50$

~~● DIMENSIONAL LIMITS APPLY BEFORE PROCESSING~~

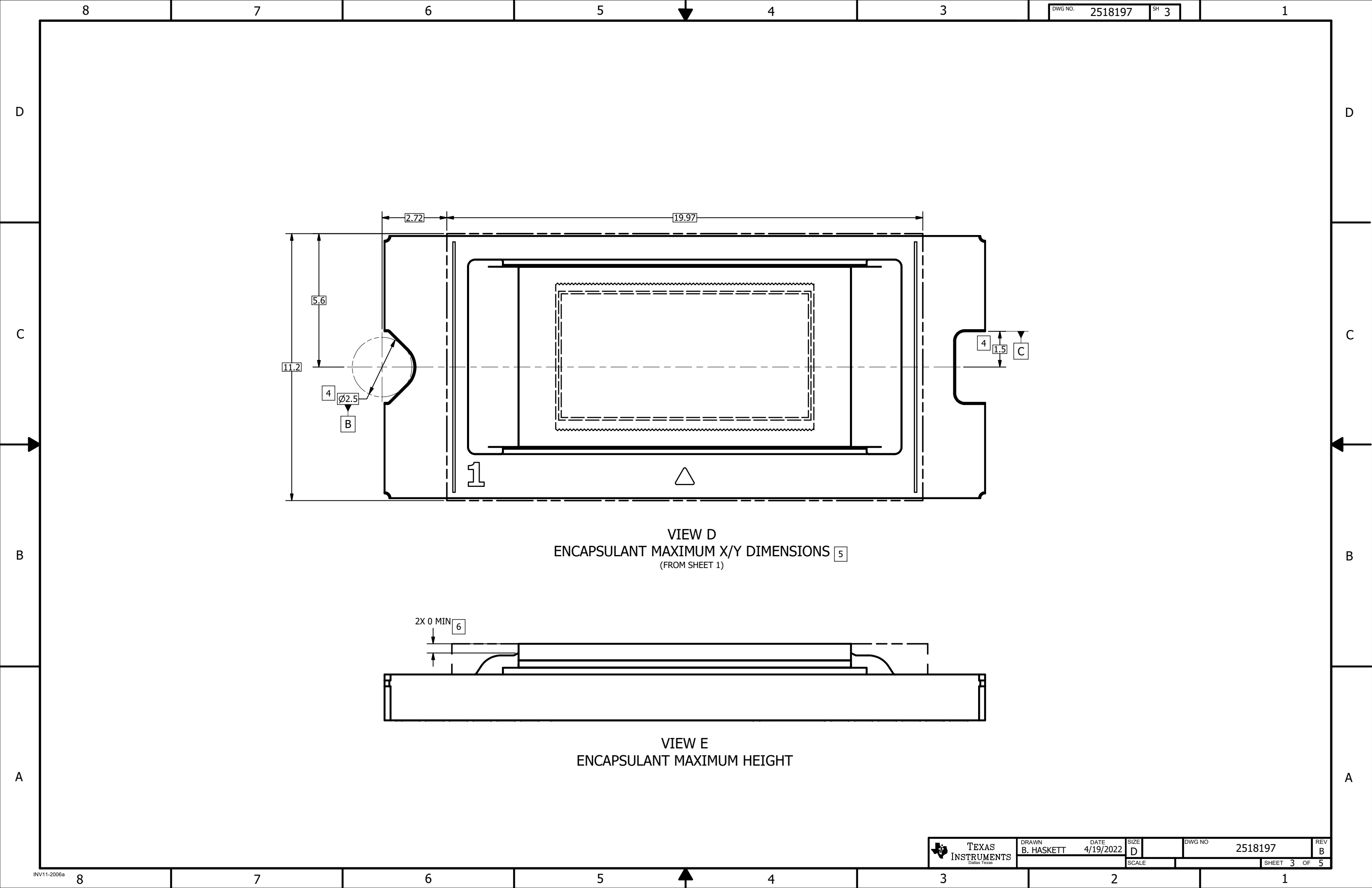
- INTERPRET DIMENSIONS IN ACCORDANCE WITH ASME Y14.5M-1994
- ~~● REMOVE ALL BURRS AND SHARP EDGES~~
- PARENTHETICAL INFORMATION FOR REFERENCE ONLY

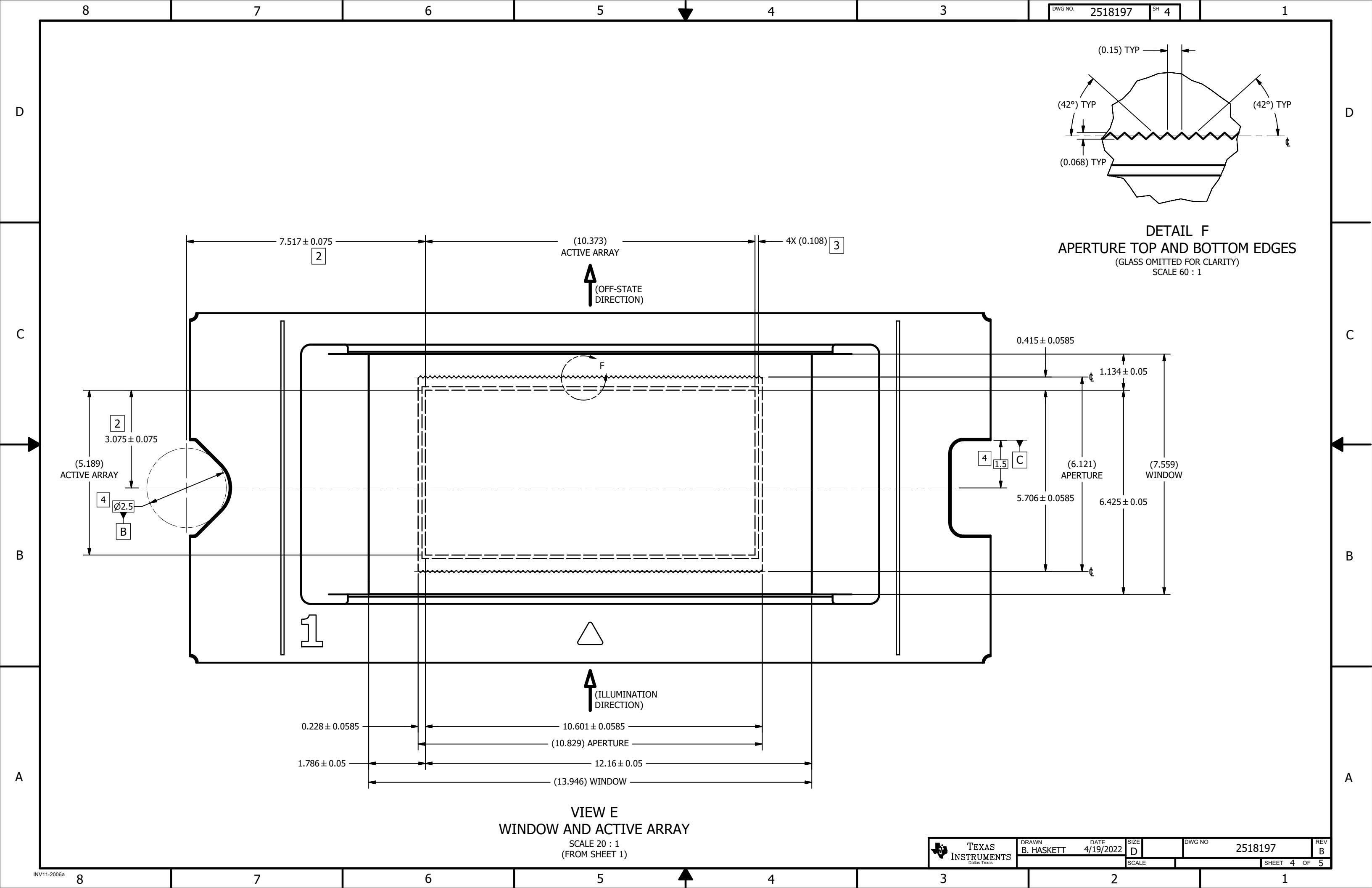
|             |           |
|-------------|-----------|
| DRAWN       | DATE      |
| B. HASKETT  | 4/19/2022 |
| ENGINEER    |           |
| B. HASKETT  | 4/19/2022 |
| QA/CE       |           |
| P. KONRAD   | 4/20/2022 |
| CM          |           |
| B. HASKETT  | 4/27/2022 |
| J. McKinLEY | 4/27/2022 |
| APPROVED    |           |
| B. RAY      | 4/21/2022 |

|                                                                                                                                                                                                      |                                                                          |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------|
|  <div style="text-align: center;"> <b>TEXAS</b><br/> <b>INSTRUMENTS</b><br/> <small>Dallas Texas</small> </div> |                                                                          |
| <b>TITLE</b><br><div style="text-align: center;"> <b>ICD, MECHANICAL, DMD,<br/>         .46 AUTO SERIES 320<br/>         (FQX PACKAGE)</b> </div>                                                    |                                                                          |
| <b>SIZE</b><br><b>D</b>                                                                                                                                                                              | <b>DWG NO</b><br><div style="text-align: center;"> <b>2518197</b> </div> |
| <b>SCALE</b> <b>15:1</b>                                                                                                                                                                             | <b>SHEET</b> <b>1</b> <b>OF</b> <b>5</b>                                 |



VIEW C  
DATUMS A AND E  
SCALE 20 : 1  
(FROM SHEET 1)





8

7

6

5

4

3

DWG NO. 2518197

SH 5

1

D

D

C

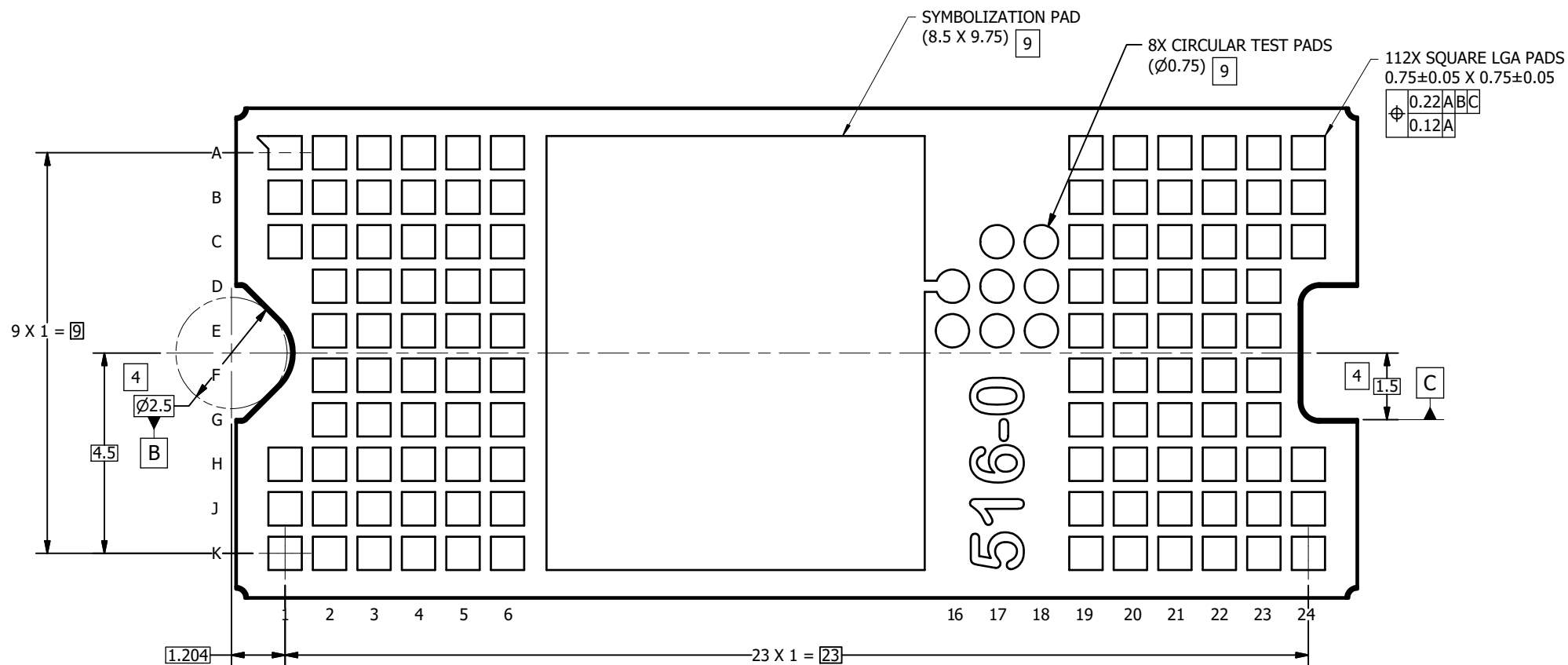
C

B

B

A

A



VIEW H-H  
BACK SIDE METALLIZATION  
SCALE 15 : 1

8

7

6

5

4

3

2

1

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